



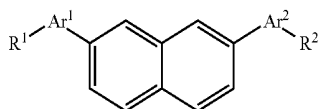
US 20130306960A1

(19) **United States**(12) **Patent Application Publication**
Yamamoto et al.(10) **Pub. No.: US 2013/0306960 A1**(43) **Pub. Date: Nov. 21, 2013**(54) **ORGANIC LIGHT EMITTING DEVICE AND MATERIALS FOR USE IN SAME**(75) Inventors: **Hitoshi Yamamoto**, Pennington, NJ (US); **Michael S. Weaver**, Princeton, NJ (US); **Julia J. Brown**, Yardley, PA (US); **Kazuki Nishimura**, Chiba (JP); **Toshihiro Iwakuma**, Chiba (JP); **Mitsunori Ito**, Chiba (JP)(73) Assignees: **Idemitsu Kosan Co., Ltd.**, Tokyo (JP); **Universal Display Corporation**, Ewing, NJ (US)(21) Appl. No.: **13/995,193**(22) PCT Filed: **Feb. 11, 2011**(86) PCT No.: **PCT/US11/24545**

§ 371 (c)(1),

(2), (4) Date: **Jun. 18, 2013****Publication Classification**(51) **Int. Cl.**
H01L 51/50 (2006.01)(52) **U.S. Cl.**
CPC **H01L 51/5028** (2013.01)
USPC **257/40**(57) **ABSTRACT**

The present invention provides an OLED in which an organic thin film emissive layer comprising a single layer or plural layers between a cathode and an anode, wherein the organic thin film layer comprises at least one organic light emitting layer, wherein at least one light emitting layer comprises at least one host material and at least one phosphorescent emitter material, wherein the host material comprises a substituted or unsubstituted hydrocarbon compound having the chemical structure represented by the following formula (1):



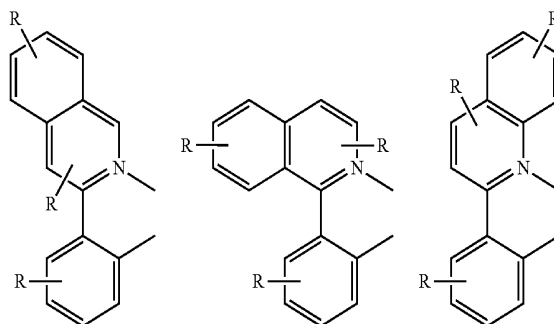
wherein R² represents a hydrogen atom, a benzene ring, a condensed aromatic hydrocarbon ring, a dibenzofuran ring or a group represented by Ar³—R³;

Ar¹ to Ar³ each independently represent a benzene ring, a condensed aromatic hydrocarbon ring or a dibenzofuran ring;

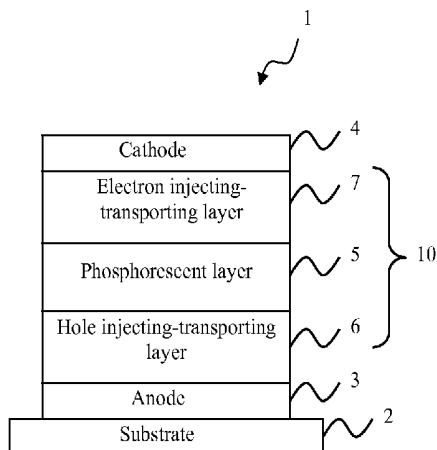
R¹ and R³ each independently represent a hydrogen atom, a benzene ring, a condensed aromatic hydrocarbon ring, or a dibenzofuran ring; the condensed aromatic hydrocarbon ring represented by R¹ to R³ and Ar¹ to Ar³ is selected from the group consisting of a naphthalene ring, a chrysene ring, a fluoranthene ring, a triphenylene ring, a phenanthrene ring, a benzophenanthrene ring, a dibenzophenanthrene ring, a benzotriphenylene ring, a benzochrysene ring, and a benzo[b]fluoranthene ring; and R¹ to R³, Ar¹ to Ar³ and 2,7-disubstituted naphthalene ring each independently may have one or more substituents; with the proviso that when Ar¹ and Ar² each represents a condensed aromatic hydrocarbon constituted by four or more-membered ring, Ar¹ and Ar² are different from each other;

wherein when Ar¹ and Ar² each represents a benzene ring, R¹ and R² cannot both be a hydrogen atom or a naphthalene ring at the same time; and when R¹ and R² each represents a hydrogen atom, Ar¹ and Ar² cannot both be a naphthalene ring at the same time or a combination of a naphthalene ring and a benzene ring; and

the phosphorescent emitter material comprises a phosphorescent organometallic complex having a substituted chemical structure represented by one of the following partial chemical structures represented by the following formulas:



wherein each R is independently selected from the group consisting of H, alkyl, alkenyl, alkynyl, CN, CF₃, CₙF₂ₙ₊₁, trifluorovinyl, CO₂R, C(O)R, NR₂, NO₂, OR, halo, aryl, heteroaryl, substituted heteroaryl or a heterocyclic group.



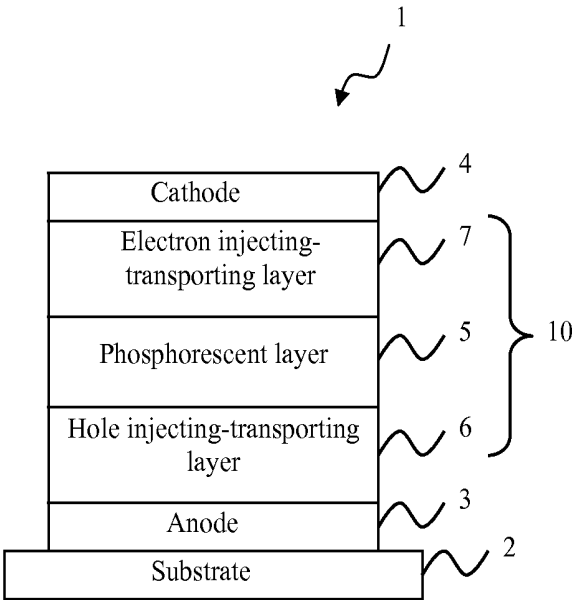


FIG. 1

ORGANIC LIGHT EMITTING DEVICE AND MATERIALS FOR USE IN SAME

BACKGROUND OF THE INVENTION

[0001] The present invention relates to an organic electroluminescent (EL) device such as an organic light emitting device (hereinafter abbreviated as an OLED) and materials capable of being used in such an OLED. In particular, it relates to an OLED which comprises a light emitting layer which emits a red light, and materials for an OLED which are used for the same.

RELATED ART

[0002] OLEDs which comprise an organic thin film layer which includes a light emitting layer located between an anode and a cathode are known in the art. In such devices, emission of light may be obtained from exciton energy, produced by recombination of a hole injected into a light emitting layer with an electron.

[0003] Generally, OLEDs are comprised of several organic layers in which at least one of the layers can be made to electroluminesce by applying a voltage across the device (see, e.g., Tang, et al., Appl. Phys. Lett. 1987, 51, 913 and Burroughes, et al., Nature, 1990, 347, 359). When a voltage is applied across a device, the cathode effectively reduces the adjacent organic layers (i.e., injects electrons), and the anode effectively oxidizes the adjacent organic layers (i.e., injects holes). Holes and electrons migrate across the device toward their respective oppositely charged electrodes. When a hole and electron meet on the same molecule, recombination is said to occur, and an exciton is formed. Recombination of the hole and electron in luminescent compounds is accompanied by radiative emission, thereby producing electroluminescence.

[0004] Depending on the spin states of the hole and electron, the exciton resulting from hole and electron recombination can have either a triplet or singlet spin state. Luminescence from a singlet exciton results in fluorescence, whereas luminescence from a triplet exciton results in phosphorescence. Statistically, for organic materials typically used in OLEDs, one quarter of the excitons are singlets, and the remaining three-quarters are triplets (see, e.g., Baldo, et al., Phys. Rev. B, 1999, 60, 14422). Until the discovery that there were certain phosphorescent materials that could be used to fabricate practical electro-phosphorescent OLEDs (U.S. Pat. No. 6,303,238) and, subsequently, demonstration that such electro-phosphorescent OLEDs could have a theoretical quantum efficiency of up to 100% (i.e., harvesting all of both triplets and singlets), the most efficient OLEDs were typically based on materials that fluoresced. Fluorescent materials luminesce with a maximum theoretical quantum efficiency of only 25% (where quantum efficiency of an OLED refers to the efficiency with which holes and electrons recombine to produce luminescence), since the triplet to ground state transition of phosphorescent emission is formally a spin forbidden process. Electro-phosphorescent OLEDs have now been shown to have superior overall device efficiencies as compared with electro-fluorescent OLEDs (see, e.g., Baldo, et al., Nature, 1998, 395, 151 and Baldo, et al., Appl. Phys. Lett. 1999, 75(3), 4).

[0005] Due to strong spin-orbit coupling that leads to singlet-triplet state mixing, heavy metal complexes often display efficient phosphorescent emission from such triplets at room

temperature. Accordingly, OLEDs comprising such complexes have been shown to have internal quantum efficiencies of more than 75% (Adachi, et al., Appl. Phys. Lett., 2000, 77, 904). Certain organometallic iridium complexes have been reported as having intense phosphorescence (Lamansky, et al., Inorganic Chemistry, 2001, 40, 1704), and efficient OLEDs emitting in the green to red spectrum have been prepared with these complexes (Lamansky, et al., J. Am. Chem. Soc., 2001, 123, 4304). Phosphorescent heavy metal organometallic complexes and their respective devices have been the subject of U.S. Pat. Nos. 6,830,828 and 6,902,830; U.S. Publications 2006/0202194 and 2006/0204785; and U.S. Pat. Nos. 7,001,536; 6,911,271; 6,939,624; and 6,835,469.

[0006] OLEDs, as described above, generally provide excellent luminous efficiency, image quality, power consumption and the ability to be incorporated into thin design products such as flat screens, and therefore hold many advantages over prior technology, such as cathode ray devices.

[0007] However, improved OLEDs, including, for example, the preparation of OLEDs having greater current efficiency are desirable. In this regard, light emitting materials (phosphorescent materials) have been developed in which light emission is obtained from a triplet exciton in order to enhance internal quantum efficiency.

[0008] As discussed above, such OLEDs can have a theoretical internal quantum efficiency up to 100% by using such phosphorescent materials in the light emitting layer (phosphorescent layer), and the resulting OLED will have a high efficiency and low power consumption. Such phosphorescent materials may be used as a dopant in a host material which comprises such a light emitting layer.

[0009] In a light emitting layer formed by doping with a light emitting material such as a phosphorescent material, excitons can efficiently be produced from a charge injected into a host material. Exciton energy of an exciton produced may be transferred to a dopant, and emission may be obtained from the dopant at high efficiency. Excitons may be formed either on the host materials or directly on the dopant.

[0010] In order to achieve intermolecular energy transfer from a host material to a phosphorescent dopant with high device efficiencies, the excited triplet energy E_gH of the host material must be greater than the excited triplet energy E_gD of the phosphorescent dopant.

[0011] In order to carry out intermolecular energy transfer from a host material to a phosphorescent dopant, an excited triplet energy $E_g(T)$ of the host material has to be larger than an excited triplet energy $E_g(S)$ of the phosphorescent dopant.

[0012] CBP (4,4'-bis(N-carbazolyl)biphenyl) is known to be a representative example of a material having an efficient and large excited triplet energy. See, e.g., U.S. Pat. No. 6,939,624. If CBP is used as a host material, energy can be transferred to a phosphorescent dopant having a prescribed emission wavelength, such as red, and an OLED having a high efficiency can be obtained. When CBP is used as a host material, the luminous efficiency is notably enhanced by phosphorescent emission. However, CBP is known to have a very short lifetime and therefore it is not suitable for practical use in EL devices such as an OLED. Without being bound by scientific theory, it is believed that this is because CBP may be heavily deteriorated by a hole due to its oxidative stability not being high, in terms of molecular structure.

[0013] International Patent Application Publication WO 2005/112519 discloses a technique in which a condensed ring

derivative having a nitrogen-containing ring such as carbazole and the like is used as a host material for a phosphorescent layer showing red phosphorescence. The current efficiency and the lifetime are improved by the above technique, but it is not satisfactory in a certain case for practical use.

[0014] On the other hand, a wide variety of host materials (fluorescent hosts) for a fluorescent dopant showing fluorescent emission are known, and various host materials can be proposed which, by combination with a fluorescent dopant, may form a fluorescent layer which exhibits excellent luminous efficiency and lifetime.

[0015] In a fluorescent host, an excited singlet energy $E_g(S)$ is larger than in a fluorescent dopant, but an excited triplet energy $E_g(T)$ of such a host is not necessarily larger. Accordingly, a fluorescent host cannot simply be used in place of a phosphorescent host as a host material to provide a phosphorescent emitting layer.

[0016] For example, anthracene derivatives are known well as a fluorescent host. However, an excited state triplet energy $E_g(T)$ of anthracene derivatives may be as small as about 1.9 eV. Thus, energy transfer to a phosphorescent dopant having an emission wavelength in a visible light region of 500 nm to 720 nm cannot be achieved using such a host, since the excited state triplet energy would be quenched by a host having such a low triplet state energy. Accordingly, anthracene derivatives are unsuitable as a phosphorescent host.

[0017] Perylene derivatives, pyrene derivatives and naphthalene derivatives are not preferred as phosphorescent hosts for the same reason.

[0018] The use of aromatic hydrocarbon compounds as phosphorescent hosts is disclosed in Japanese Patent Application Laid-Open No. 142267/2003. That application discloses phosphorescent host compounds with a benzene skeleton core and with two aromatic substituents bonded at meta positions.

[0019] However, the aromatic hydrocarbon compounds described in Japanese Patent Application Laid-Open No. 142267/2003 assume a rigid molecular structure having a good symmetric property and provided with five aromatic rings in which molecules are arranged in a bilaterally symmetrical manner toward a central benzene skeleton. Such an arrangement has the drawback of a likelihood of crystallization of the light emitting layer.

[0020] On the other hand, OLEDs in which various aromatic hydrocarbon compounds are used are disclosed in International Patent Application Publications WO 2007/046685; Japanese Patent Application Laid-Open No. 151966/2006; Japanese Patent Application Laid-Open No. 8588/2005; Japanese Patent Application Laid-Open No. 19219/2005; Japanese Patent Application Laid-Open No. 19219/2005; and Japanese Patent Application Laid-Open No. 75567/2004. However, the efficiency of these materials as a phosphorescent host is not disclosed.

[0021] In addition, OLEDs prepared by using various fluorene compounds are disclosed in Japanese Patent Application Laid-Open No. 043349/2004; Japanese Patent Application Laid-Open No. 314506/2007; and Japanese Patent Application Laid-Open No. 042485/2004. However, the effectiveness of these materials as a phosphorescent host is not disclosed.

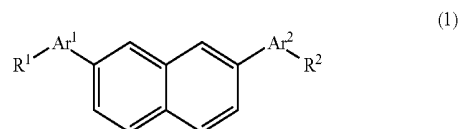
[0022] Further, Japanese Patent Application Laid-Open No. 042485/2004 discloses hydrocarbon compounds in which a condensed polycyclic aromatic ring is bonded directly to a fluorene ring. However, the effectiveness of an

OLED prepared by combining such materials with a phosphorescent material is not disclosed, and the application discloses perylene and pyrene rings which are known to have a small triplet energy level as condensed polycyclic aromatic rings, and which are not preferred for use as a light emitting layer of a phosphorescent device, and materials which are effective for a phosphorescent device are not selected.

[0023] Despite the recent discoveries of efficient heavy metal phosphors and the resulting advancements in OLED technology, there remains a need for even greater high temperature device stability. In addition, there still remains a need for host materials which can transfer energy to a phosphorescent material with high efficiency and with an extended lifetime. Fabrication of devices that have longer high temperature lifetimes will contribute to the development of new display technologies and help realize the current goals toward full color electronic display on flat surfaces. The OLEDs and the host materials and phosphorescent emitter materials comprised in such OLEDs, described herein, help fulfill this objective.

SUMMARY OF THE INVENTION

[0024] The OLEDs of the present invention are characterized by providing an organic thin film layer comprising a single layer or plural layers between a cathode and an anode, wherein the organic thin film layer comprises at least one organic light emitting layer, wherein at least one light emitting layer comprises at least one host material and at least one phosphorescent emitter material, wherein the host material comprises a substituted or unsubstituted hydrocarbon compound having the chemical structure represented by the following formula (1):



[0025] wherein R^2 represents a hydrogen atom, a benzene ring, a condensed aromatic hydrocarbon ring, a dibenzofuran ring or a group represented by Ar^3-R^3 ;

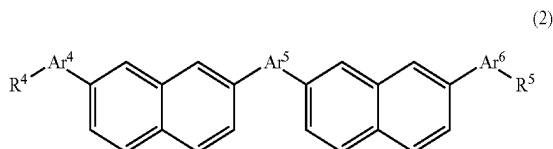
[0026] Ar^1 to Ar^3 each independently represent a benzene ring, a condensed aromatic hydrocarbon ring or a dibenzofuran ring;

[0027] R^1 and R^3 each independently represent a hydrogen atom, a benzene ring, a condensed aromatic hydrocarbon ring, or a dibenzofuran ring; the condensed aromatic hydrocarbon ring represented by R^1 to R^3 and Ar^1 to Ar^3 is selected from the group consisting of a naphthalene ring, a chrysene ring, a fluoranthene ring, a triphenylene ring, a phenanthrene ring, a benzophenanthrene ring, a dibenzophenanthrene ring, a benzotriphenylene ring, a benzochrysene ring, and a benzo[b]fluoranthene ring; and R^1 to R^3 , Ar^1 to Ar^3 and 2,7-disubstituted naphthalene ring each independently may have one or more substituents; with the proviso that when Ar^1 and Ar^2 each represents a condensed aromatic hydrocarbon constituted by a four or more-membered ring, Ar^1 and Ar^2 are different from each other;

[0028] wherein when Ar^1 and Ar^2 each represents a benzene ring, R^1 and R^2 cannot both be a hydrogen atom or a naphthalene ring at the same time; and when R^1 and R^2 each represent a hydrogen atom, Ar^1 and Ar^2 cannot both be a

naphthalene ring at the same time or a combination of a naphthalene ring and a benzene ring.

[0029] An alternative structure for the host material has the following formula (2):

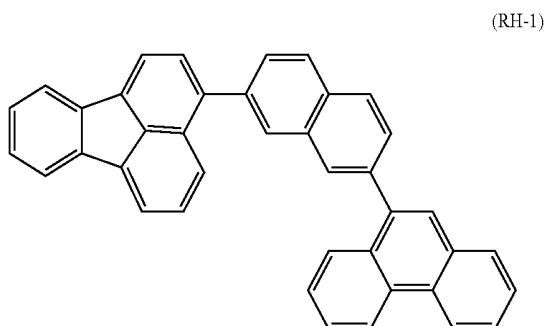


[0030] where Ar⁴-Ar⁶ are each independently a benzene ring, fused aromatic hydrocarbon ring, or represent a dibenzofuran ring;

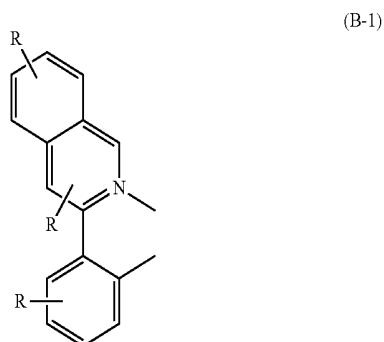
[0031] and R⁴, R⁵ are each independently a hydrogen atom, benzene ring, fused aromatic hydrocarbon ring, or represent a dibenzofuran ring;

[0032] R⁴, R⁵, Ar⁴-Ar⁶ and fused aromatic hydrocarbon ring are each independently a naphthalene ring, chrysene ring, fluoranthene ring, triphenylene ring, phenanthrene ring, ring benzophenanthrene, or a benzophenanthrene ring, and additional structures as described below.

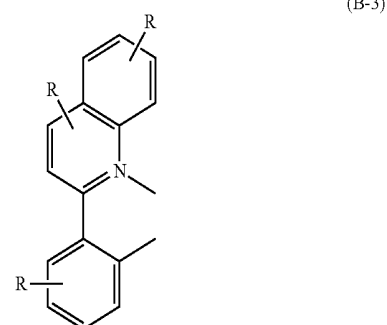
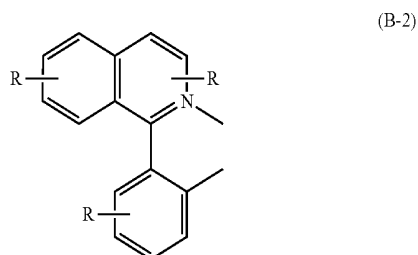
[0033] In another embodiment, the OLED comprises a host material having the chemical structure represented by the formula (RH-1):



[0034] In one embodiment of the present invention, the phosphorescent emitter material comprises a phosphorescent organometallic complex having a substituted chemical structure represented by one of the following partial chemical structures represented by the following formulas (B-1), (B-2) and (B-3):

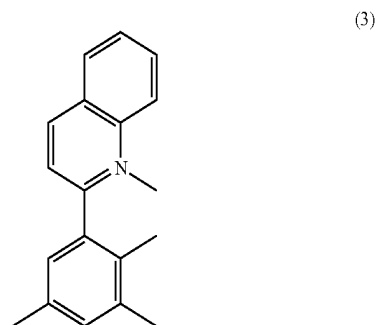


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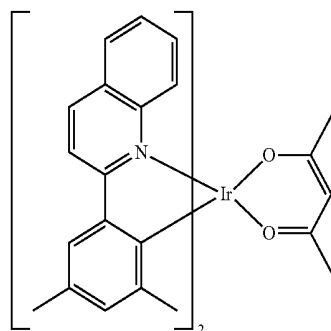
[0035] wherein each R is independently selected from the group consisting of H, alkyl, alkenyl, alkynyl, CN, CF₃, C_nF_{2n+1}, trifluorovinyl, CO₂R, C(O)R, NR₂, NO₂, OR, halo, aryl, heteroaryl, substituted heteroaryl or a heterocyclic group.

[0036] In another embodiment, the phosphorescent emitter material comprises a phosphorescent organometallic complex having a substituted chemical structure represented by the following partial chemical structure (3):

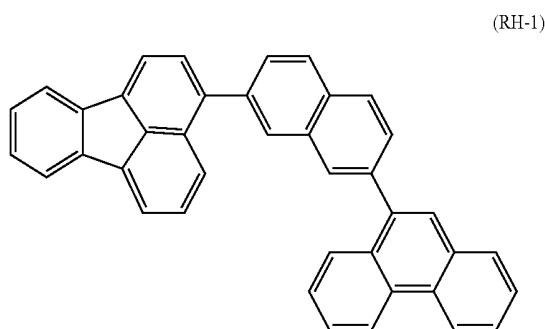


[0037] In another embodiment, the phosphorescent emitter material comprises a metal complex, and the metal complex comprises a metal atom selected from Ir, Pt, Os, Au, Cu, Re and Ru and a ligand. In yet another embodiment the metal complex has an ortho-metal bond. In preferred embodiments, Ir is the metal atom.

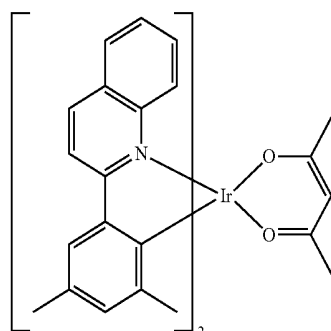
[0038] In another embodiment, the phosphorescent emitter material comprises a phosphorescent organometallic compound having a substituted chemical structure represented by the following chemical structure (4):



[0039] In another embodiment, the present invention comprises an OLED which comprises a host material which comprises an unsubstituted aromatic hydrocarbon compound having the chemical structure represented by the following formula (RH-1):

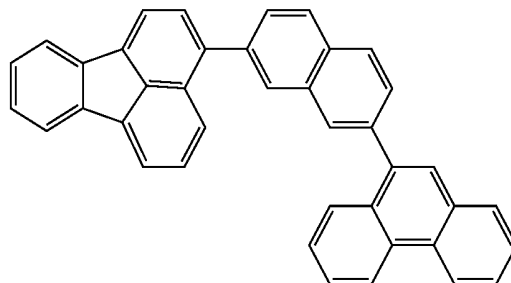


[0040] and a phosphorescent emitter material which comprises a phosphorescent organometallic compound having a substituted chemical structure represented by the following chemical structure (4):



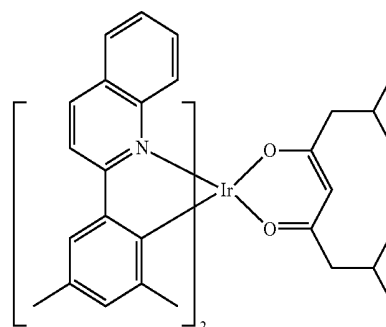
[0041] In another embodiment, the present invention comprises an OLED which comprises a host material which comprises an unsubstituted aromatic hydrocarbon compound having the chemical structure represented by the following formula (RH-1):

(4)



(RH-1)

[0042] and a phosphorescent emitter material which comprises a phosphorescent organometallic compound having a substituted chemical structure represented by the following chemical structure (RD-1):



(RD-1)

[0043] In one embodiment, the present invention comprises an OLED which comprises a host material, wherein the excited triplet energy of the host material is from about 2.0 eV to about 2.8 eV.

[0044] In another embodiment, the present invention comprises an OLED which comprises at least one phosphorescent material in the light emitting layer, wherein the phosphorescent material has a maximum value of 500 nm or more and 720 nm or less in a light emitting wavelength.

[0045] In another embodiment, the present invention comprises an OLED which provides improved voltage and working lifetime characteristics. Without being bound by theory, it is believed that improved characteristics of the OLEDs of the present invention may be achieved due to the serial bonding of two or more condensed polycyclic aromatic rings to a monovalent fluorene skeleton and by bonding a group containing condensed polycyclic aromatic rings which are different from each other to a fluorene skeleton in a position in which a conjugate length is extended.

[0046] In another embodiment, the present invention comprises a phosphorescent OLED having high efficiency and long lifetime, which OLED comprises a material of general Formula (1) as a host material, and particularly as a phosphorescent host material.

BRIEF DESCRIPTION OF THE DRAWING

[0047] FIG. 1 is a drawing showing an outline constitution of one example of the OLED in the embodiment of the present invention.

DETAILED DESCRIPTION

[0048] The OLEDs of the present invention may comprise a plurality of layers located between an anode and a cathode. Representative OLEDs according to the invention include, but are not limited to, structures having constituent layers as described below:

[0049] (1) Anode/light emitting layer/cathode;

[0050] (2) Anode/hole injecting layer/light emitting layer/cathode;

[0051] (3) Anode/light emitting layer/electron injecting*transporting layer/cathode;

[0052] (4) Anode/hole injecting layer/light emitting layer/electron injecting*transporting layer/cathode;

[0053] (5) Anode/organic semiconductor layer/light emitting layer/cathode;

[0054] (6) Anode/organic semiconductor layer/electron blocking layer/light emitting layer/cathode;

[0055] (7) Anode/organic semiconductor layer/light emitting layer/adhesion improving layer/cathode;

[0056] (8) Anode/hole injecting*transporting layer/light emitting layer/electron injecting*transporting layer/cathode;

[0057] (9) anode/insulating layer/light emitting layer/insulating layer/cathode;

[0058] (10) anode/inorganic semiconductor layer/insulating layer/light emitting layer/insulating layer/cathode;

[0059] (11) anode/organic semiconductor layer/insulating layer/light emitting layer/insulating layer/cathode;

[0060] (12) anode/insulating layer/hole injecting*transporting layer/light emitting layer/insulating layer/cathode; and

[0061] (13) anode/insulating layer/hole injecting*transporting layer/light emitting layer/electron injecting*transporting layer/cathode.

[0062] Among the OLED constituent structures described above, constitution structure number 8 is a preferred structure, but the present invention is not limited to these disclosed constituent structures.

[0063] A schematic constitution of one example of an OLED in an embodiment of the present invention is shown in FIG. 1. As a representative embodiment of the invention, an OLED 1 comprises a transparent substrate 2, an anode 3, a cathode 4 and an organic thin film layer 10 disposed between the anode 3 and the cathode 4.

[0064] The organic thin film layer 10 comprises a phosphorescence emitting layer 5 containing a phosphorescent host and a phosphorescent dopant, and can provide respectively a hole injecting*transporting layer 6 and the like between the phosphorescence emitting layer 5 and the anode 3, and an electron injecting*transporting layer 7 and the like between the phosphorescence emitting layer 5 and the cathode 4.

[0065] Further, there may be provided respectively an electron blocking layer disposed between the anode 3 and the phosphorescence emitting layer 5, and a hole blocking layer disposed between the cathode 4 and the phosphorescence emitting layer 5. This makes it possible to contain electrons and holes in the phosphorescence emitting layer 5 to enhance the production rate of excitons in the phosphorescence emitting layer 5.

[0066] In the present specification, the terms “fluorescent host” and “phosphorescent host” are referred to as a fluorescent host when combined with a fluorescent dopant and as a phosphorescent host when combined with a phosphorescent

dopant, respectively, and should not be limited to a classification of the host material based solely on molecular structure.

[0067] Accordingly, a fluorescent host in the present specification means a material constituting the fluorescence emitting layer containing a fluorescent dopant and does not mean a material which can be used only for a host of a fluorescent material.

[0068] Similarly, a phosphorescent host means a material constituting the phosphorescence emitting layer containing a phosphorescent dopant and does not mean a material which can be used only for a host of a phosphorescent material.

[0069] In the present specification, “a hole injecting*transporting layer” means at least either one of a hole injecting layer and a hole transporting layer, and “an electron injecting*transporting layer” means at least either one of an electron injecting layer and an electron transporting layer.

Substrate

[0070] The OLED of the present invention may be prepared on a substrate. The substrate referred to in this case is a substrate for supporting the OLED, and it is preferably a flat substrate in which light in the visible region of about 400 to about 700 nm has a transmittance of at least about 50%.

[0071] The substrate may include a glass plate, a polymer plate and the like. In particular, the glass plate may include soda lime glass, barium*strontium-containing glass, lead glass, aluminosilicate glass, borosilicate glass, barium borosilicate glass, quartz and the like. The polymer plate may include polycarbonate, acryl, polyethylene terephthalate, polyether sulfide, polysulfone and the like.

Anode and Cathode

[0072] An anode in the OLED of the present invention assumes the role of injecting a hole into the hole injecting layer, the hole transporting layer or the light emitting layer. Typically the anode has a work function of 4.5 eV or more. Specific examples of a material suitable for use as the anode include indium tin oxide alloy (ITO), tin oxide (NESA), indium zinc oxide, gold, silver, platinum, copper and the like. The anode can be prepared by forming a thin film from electrode substances, such as those discussed above, by a method such as a vapor deposition method, a sputtering method and the like.

[0073] When light is emitted from the light emitting layer, the transmittance of light in the visible light region in the anode is preferably larger than 10%. The sheet resistance of the anode is preferably several hundred Ω /square or less. The film thickness of the anode is selected, depending on the material, and is typically in the range of from about 10 nm to about 1 μ m, and preferably from about 10 nm to about 200 nm.

[0074] The cathode comprises preferably a material having a small work function for the purpose of injecting an electron into the electron injecting layer, the electron transporting layer or the light emitting layer. Materials suitable for use as the cathode include, but are not limited to indium, aluminum, magnesium, magnesium-indium alloys, magnesium-aluminum alloys, aluminum-lithium alloys, aluminum-scandium-lithium alloys, magnesium-silver alloys and the like. For transparent or top-emitting devices, a TOLED cathode such as disclosed in U.S. Pat. No. 6,548,956 is preferred.

[0075] The cathode can be prepared, as is the case with the anode, by forming a thin film by a method such as a vapor deposition method, a sputtering method and the like. Further, an embodiment in which light emission is taken out from a cathode side can be employed as well.

Light Emitting Layer

[0076] The light emitting layer in the OLED may be capable of carrying out the following functions singly or in combination:

[0077] (1) injecting function: a function in which a hole can be injected from an anode or a hole injecting layer in applying an electric field and in which an electron can be injected from a cathode or an electron injecting layer;

[0078] (2) transporting function: a function in which a charge (electron and hole) injected may be transferred by virtue of a force of an electric field; and

[0079] (3) light emitting function: a function in which a region for recombination of an electron and a hole may be provided, and which results in the emission of light.

[0080] A difference may be present between ease of injection of a hole and ease of injection of an electron, and a difference may be present in the transporting ability shown by the mobilities of a hole and an electron.

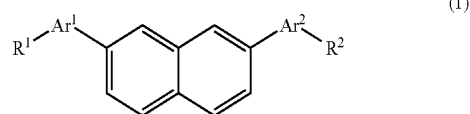
[0081] Known methods including, for example, vapor deposition, spin coating, Langmuir Blodgett methods and the like can be used to prepare the light emitting layer. The light emitting layer is preferably a molecularly deposited film. In this regard, the term "molecularly deposited film" means a thin film formed by depositing a compound from the gas phase and a film formed by solidifying a material compound in a solution state or a liquid phase state, and usually the above-referenced molecular deposit film can be distinguished from a thin film (molecular accumulation film) formed by an LB method by a difference in an aggregation structure and a higher order structure and a functional difference originating in it.

[0082] In preferred embodiments, the film thickness of the light emitting layer is preferably from about 5 to about 50 nm, more preferably from about 7 to about 50 nm and most preferably from about 10 to about 50 nm. If the film thickness is less than 5 nm, it is likely to be difficult to form the light emitting layer and control the chromaticity. On the other hand, if it exceeds about 50 nm, the operating voltage is likely to go up.

OLEDs

[0083] In an OLED of the present invention, an organic thin film layer comprising one layer or plural layers is provided between a cathode and an anode; the above organic thin film layer comprises at least one light emitting layer; and at least one of the organic thin film layers contains at least one phosphorescent material and at least one host material as described below. Further, at least one of the light emitting layers contains preferably at least one host material of the present invention for an organic electroluminescence device and at least one phosphorescent material.

[0084] In the present invention, the light emitting layer comprises at least one phosphorescent material capable of phosphorescence emission, and a host material represented by the following formula (1):



[0085] In the formula (1) described above, R² represents a hydrogen atom, a benzene ring, a condensed aromatic hydrocarbon ring, a dibenzofuran ring or a group represented by Ar³-R³;

[0086] Ar¹ to Ar³ each independently represent a benzene ring, a condensed aromatic hydrocarbon ring or a dibenzofuran ring;

[0087] R¹ and R³ each independently represent a hydrogen atom, a benzene ring, a condensed aromatic hydrocarbon ring, or a dibenzofuran ring; the condensed aromatic hydrocarbon ring represented by R¹ to R³ and Ar¹ to Ar³ is selected from the group consisting of a naphthalene ring, a chrysene ring, a fluoranthene ring, a triphenylene ring, a phenanthrene ring, a benzophenanthrene ring, a dibenzophenanthrene ring, a benzotriphenylene ring, a benzochrysene ring, and a benzo [b]fluoranthene ring; and R¹ to R³, Ar¹ to Ar³ and 2,7-disubstituted naphthalene ring each independently may have one or more substituents; with the proviso that when Ar¹ and Ar² each represents a condensed aromatic hydrocarbon constituted by four or more-membered ring, Ar¹ and Ar² are different from each other;

[0088] wherein when Ar¹ and Ar² each represents a benzene ring, R¹ and R² cannot both be a hydrogen atom or a naphthalene ring at the same time; and when R¹ and R² each represents a hydrogen atom, Ar¹ and Ar² cannot both be a naphthalene ring at the same time or a combination of a naphthalene ring and a benzene ring. The host material represented by the formula (1) described above has a large excited triplet energy gap (excited triplet energy), and therefore it can transfer energy to the phosphorescent dopant to carry out phosphorescence emission.

[0089] A thin film for an OLED which demonstrates excellent stability can be formed by selecting a suitable ring structure for the host material, and using the ring structure together with a red phosphorescent material in order to provide a device having high efficiency and long lifetime.

[0090] Anthracene derivatives, which are well known fluorescent host materials, are typically unsuitable as host materials for a phosphorescent dopant for red light emission. However, the host material of the present invention has a large excited triplet energy gap and therefore makes it possible to allow a phosphorescent dopant which displays red light emission to effectively emit light.

[0091] CBP, which is well known as a phosphorescent host, functions as a host for phosphorescent dopants which have wavelengths greater than that of green light. The host materials of the present invention allow for light emission in phosphorescent dopants which exhibit emission at wavelengths above green light emission.

[0092] In the present invention, employing a polycyclic condensed ring containing no nitrogen atom as the skeleton of the host material makes it possible to enhance the stability of the host molecules and extend the device lifetime. In this case, if the skeleton part has too small a number of ring carbon atoms, the stability of the molecules is not believed to be sufficiently enhanced.

[0093] In this case, if the skeleton portion of the host material has too small a number of ring carbon atoms, the stability of the molecules may not be sufficiently enhanced. On the other hand, if the polycyclic condensed ring has too many ring carbon atoms, the HOMO-LUMO gap may be narrowed, and an excited triplet energy gap may not produce a useful light emitting wavelength. In the present invention, the host material represented by the formula (1) described above provides a material which has a suitable number of ring carbon atoms and which therefore is suitable for use as a phosphorescent host for a phosphorescence emission layer having a useful light emitting wavelength and having a high stability, especially at higher operating temperatures.

[0094] Host materials corresponding to phosphorescent dopants which can widely be applied to phosphorescent dopants in a broad wavelength region of green to red colors are known, and therefore CBP and the like, which have a wide excited triplet energy gap, have been used for a host material. CBP has a wide excited triplet energy gap $E_g(T)$ but is associated with the problem that may have a short lifetime.

[0095] In this regard, the host material of the present invention cannot typically be applied to a host for a phosphorescent dopant having such a wide excited triplet energy gap as that of blue wavelength light, but it may function as a host for a phosphorescent dopant at wavelengths of, for example, red or green light. Further, if the excited triplet energy gap is wide, as is the case with CBP, the potential problem exists that intermolecular transfer of energy may not be efficiently carried out to a red phosphorescent dopant because of the large difference in energy gap. In the host materials described herein, however, since the energy gap may be preferably selected in combination with red or green phosphorescent dopant, energy can efficiently be transferred to the phosphorescent dopant, and a phosphorescence emitting layer having a very high efficiency can be constituted.

[0096] As described above, a phosphorescence emitting layer having high efficiency and long lifetime can be prepared according to the teachings of the present invention, especially a high stability at high operating temperatures.

[0097] In this regard, an excited triplet energy gap $E_g(T)$ of the material constituting the OLED of the invention may be prescribed based on its phosphorescence emission spectrum, and it is given as an example in the present invention that the energy gap may be prescribed, as is commonly used, in the following manner.

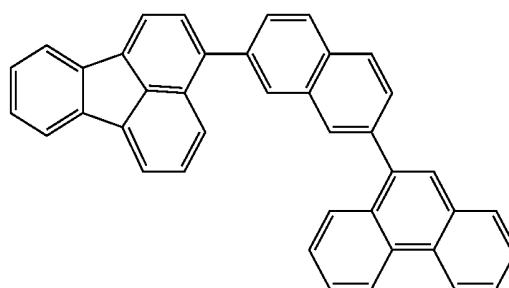
[0098] The respective materials are dissolved in an EPA solvent (diethyl ether:isopentane:ethanol=5:5:2 in terms of a volume ratio) in a concentration of 10 mmol/L to prepare a sample for measuring phosphorescence. This phosphorescence measuring sample is placed in a quartz cell and cooled

to 77 K, and is subsequently irradiated with exciting light to measure the wavelength of a phosphorescence emitted.

[0099] A tangent line is drawn based on the increase of phosphorescence emission spectrum thus obtained at the short wavelength side, and the wavelength value of the intersection point of the above tangent line and the base line is converted to an energy value, which is set as an excited triplet energy gap $E_g(T)$. A commercially available measuring equipment F-4500 (manufactured by Hitachi, Ltd.) can be used for the measurement. However, a value which can be defined as the triplet energy gap can be used without depending on the above procedure as long as it does not deviate from the scope of the present invention.

[0100] A preferred host material has the chemical structure represented by the following formula (RH-1):

(RH-1)

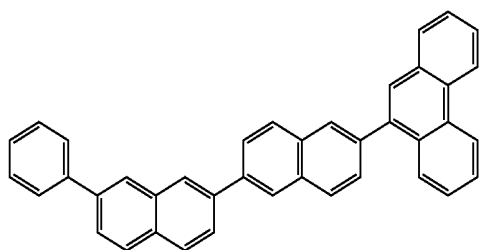


[0101] The materials of the present invention for an organic electroluminescence device have a large triplet energy gap $E_g(T)$ (excited triplet energy), and therefore phosphorescent light can be emitted by transferring energy to a phosphorescent dopant.

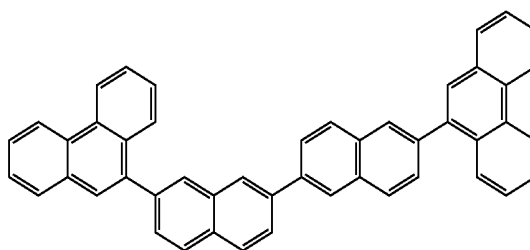
[0102] In the present invention, the excited triplet energy of the host material described above is preferably from about 2.0 eV to about 2.8 eV. The excited triplet energy of about 2.0 eV or more makes it possible to transfer energy to a phosphorescent dopant material which emits light at a wavelength of 500 nm or more and 720 nm or less. The excited triplet energy of about 2.8 eV or less makes it possible to avoid the problem that light emission is not efficiently carried out in a red phosphorescent dopant because of the large difference in an energy gap. The excited triplet energy of the host material is more preferably from about 2.1 eV to about 2.7 eV.

[0103] Some specific examples of suitable compounds for the host material according to the present invention, represented by the following formulas, include, but are not limited to, the following compounds:

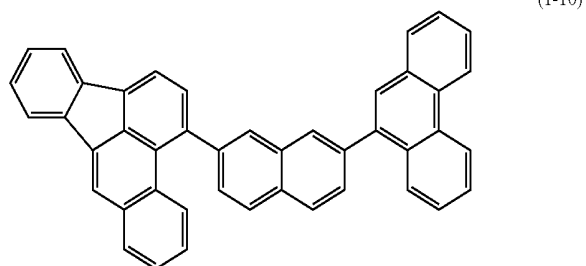
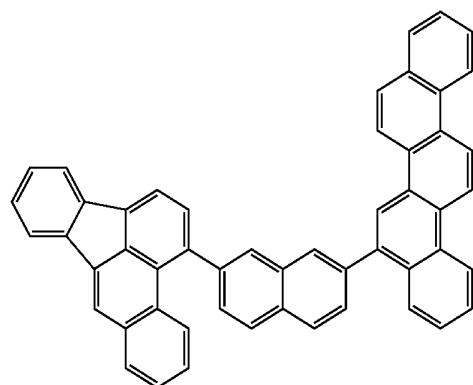
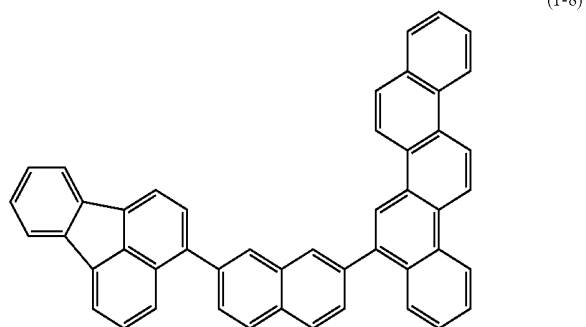
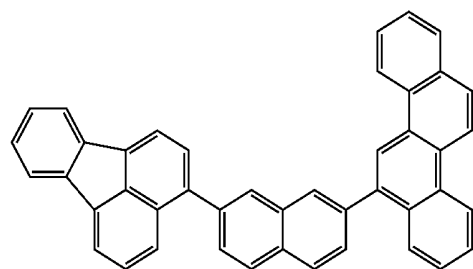
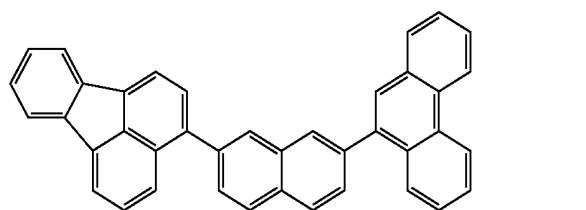
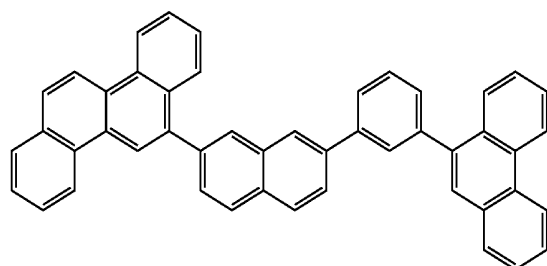
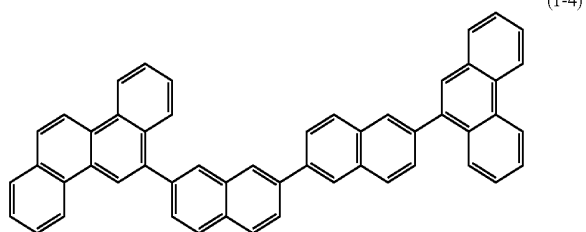
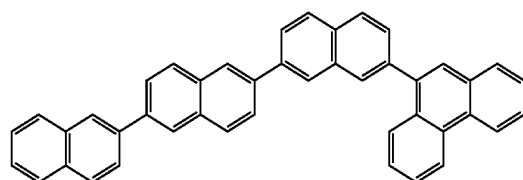
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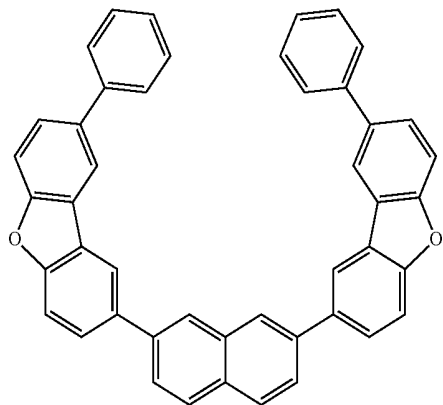


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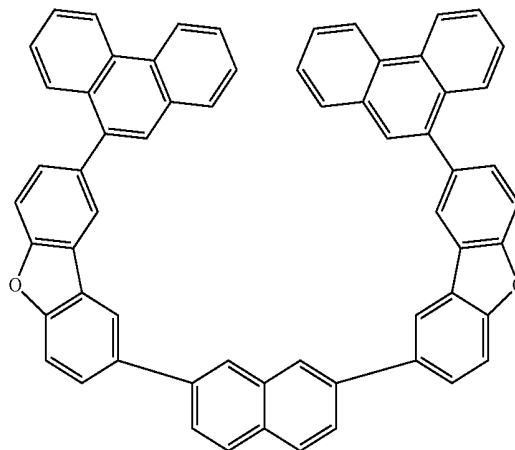


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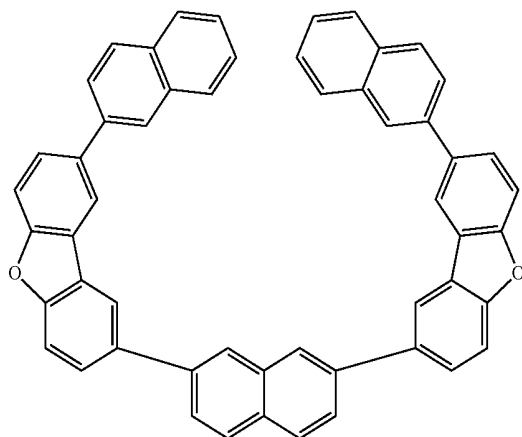
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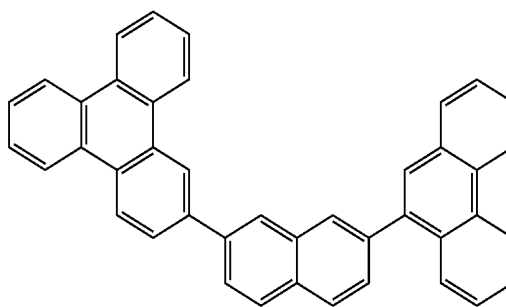
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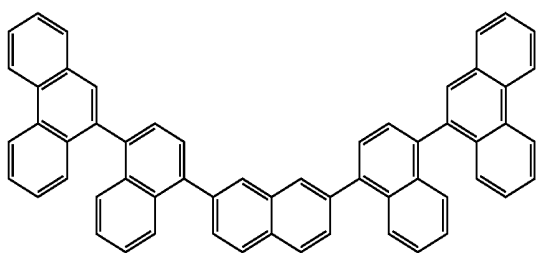
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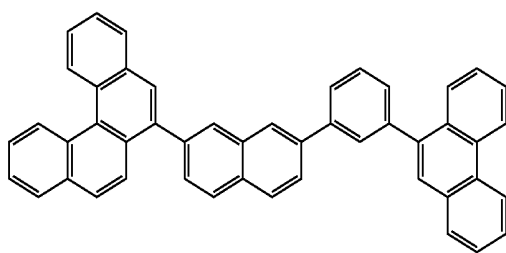
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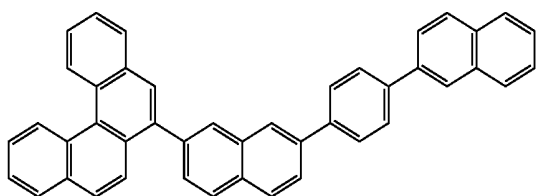
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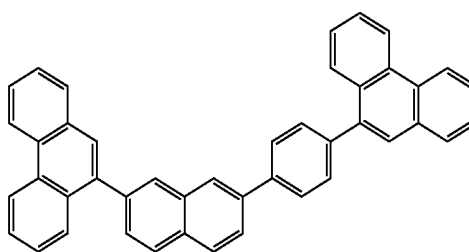
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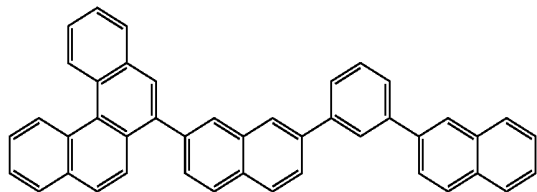


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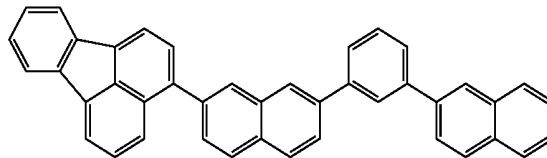


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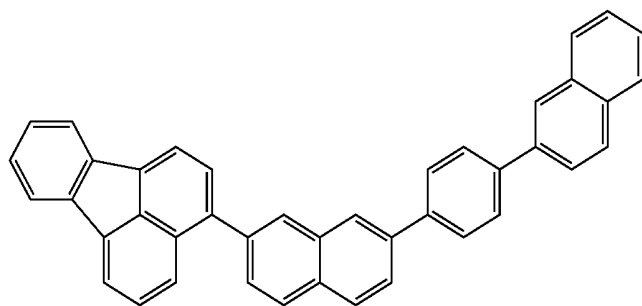
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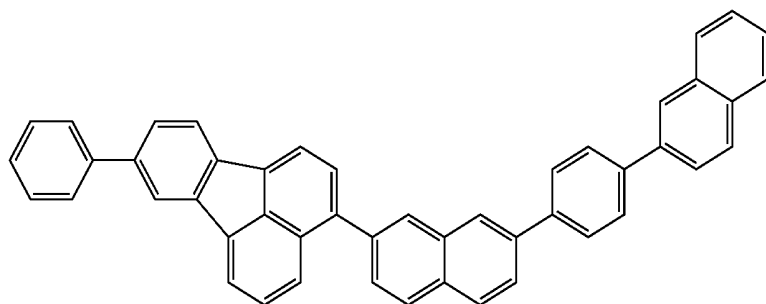
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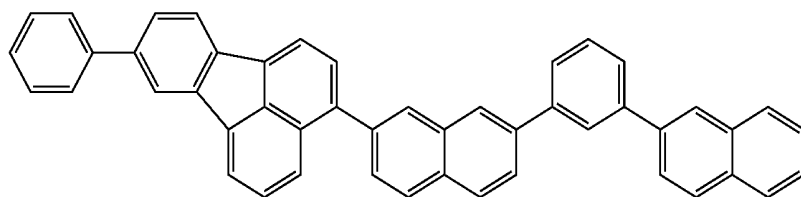
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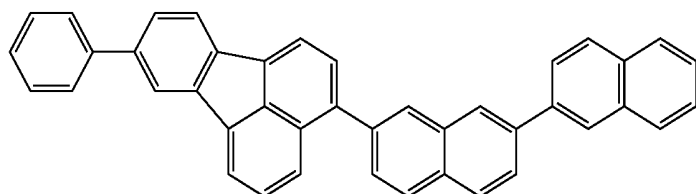
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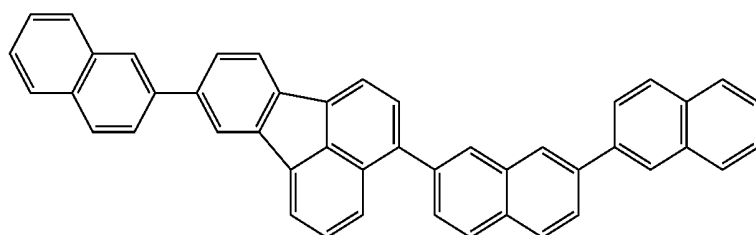
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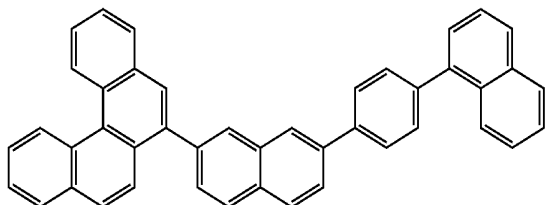


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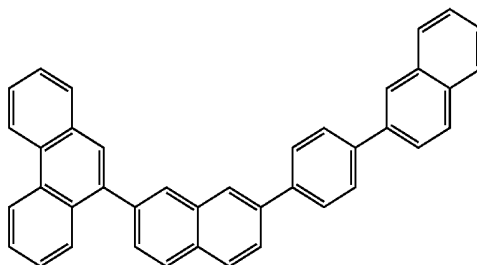


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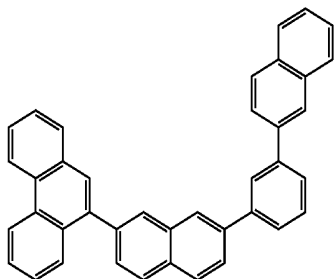
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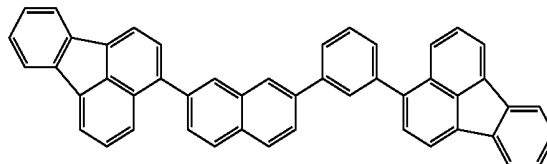
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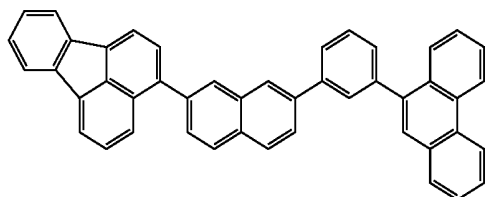
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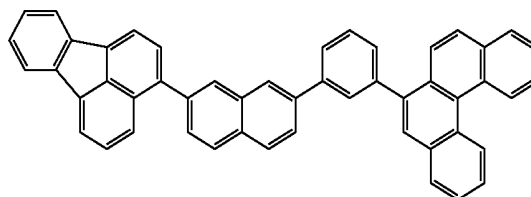
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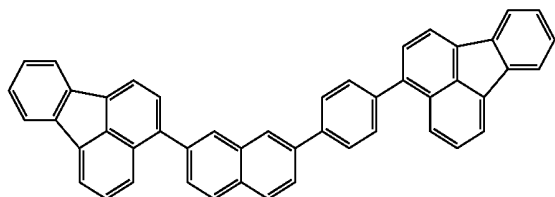
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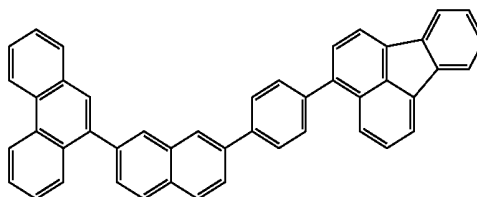
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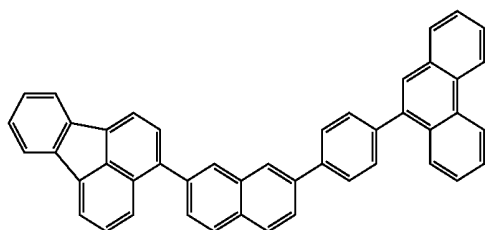
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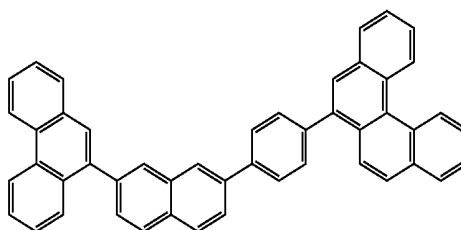
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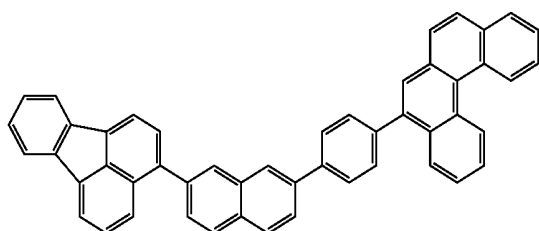
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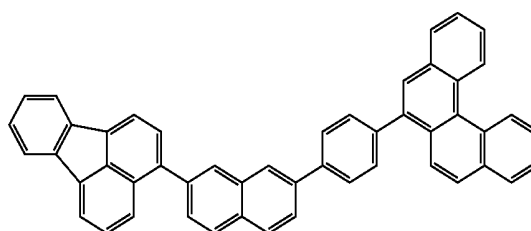
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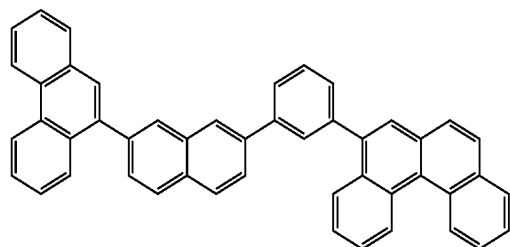
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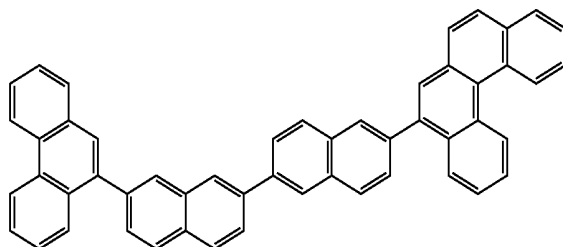
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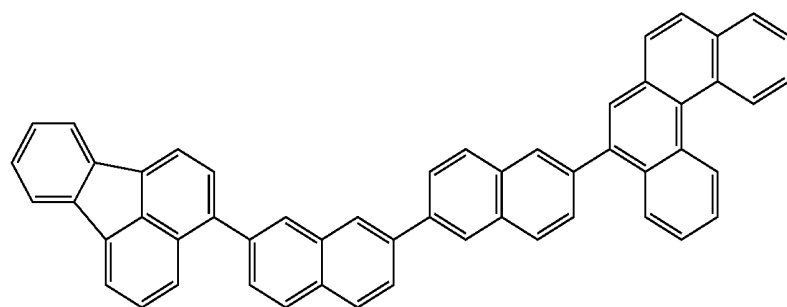
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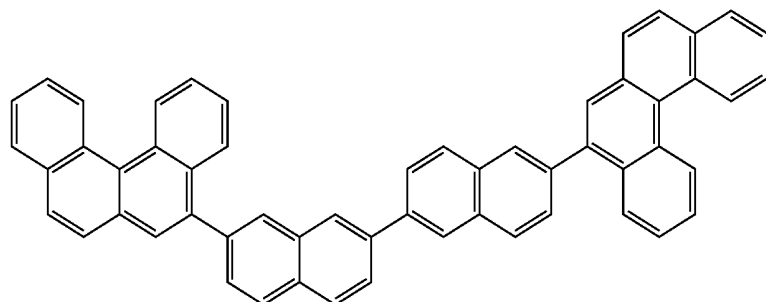
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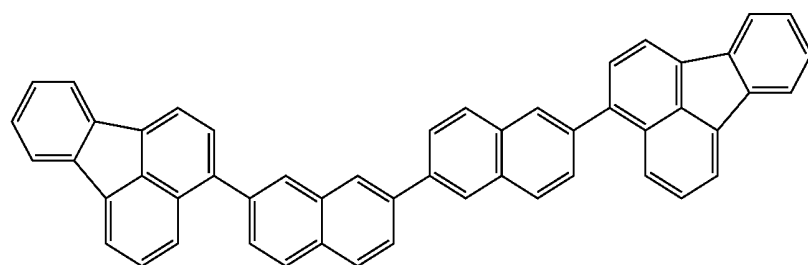
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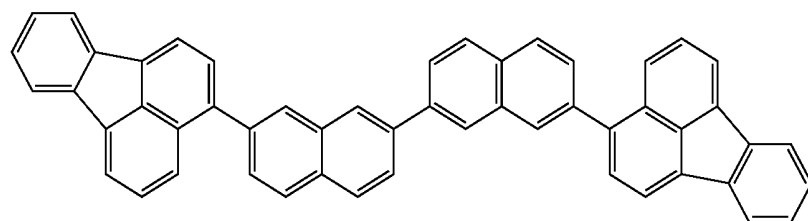
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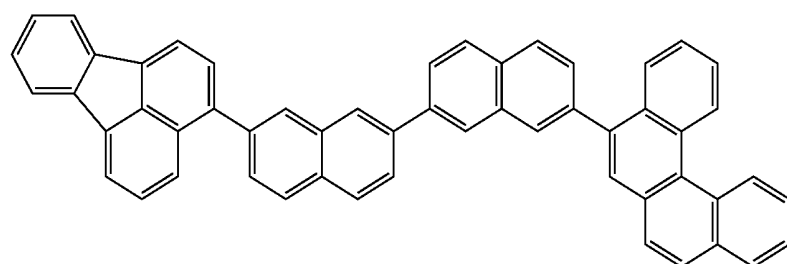
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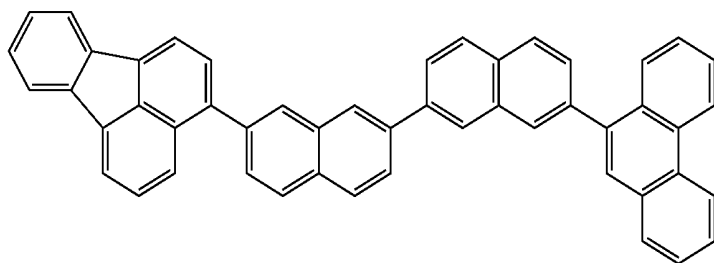


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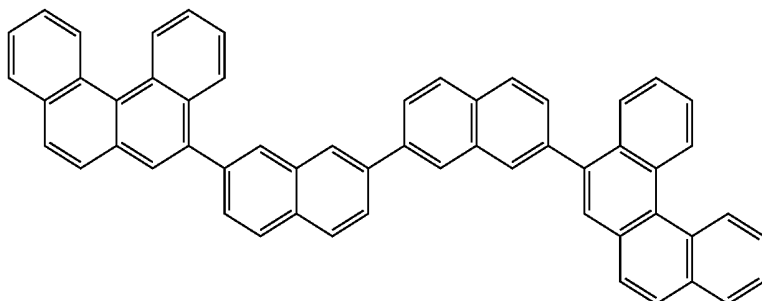


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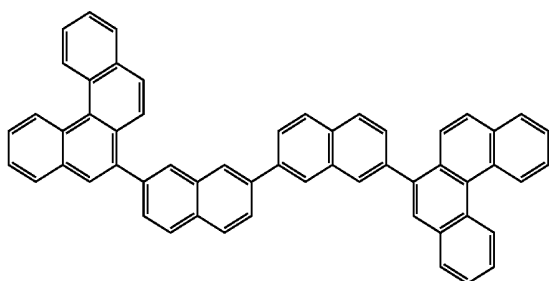
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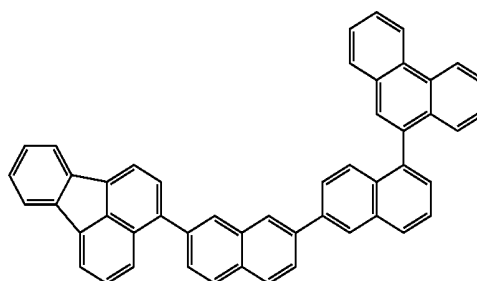
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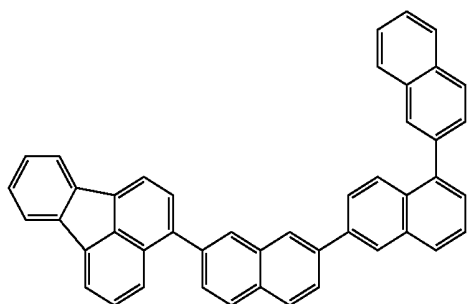
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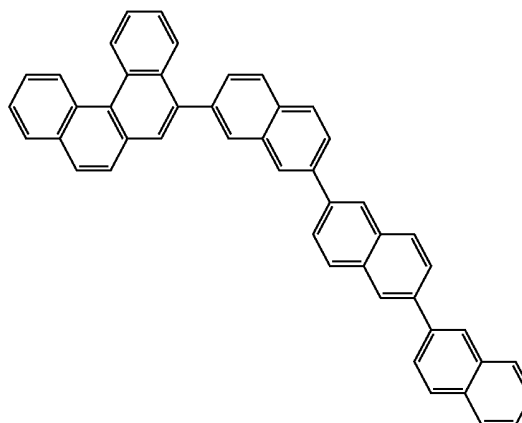
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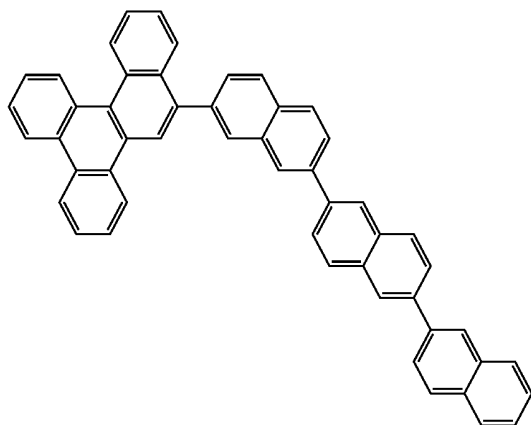


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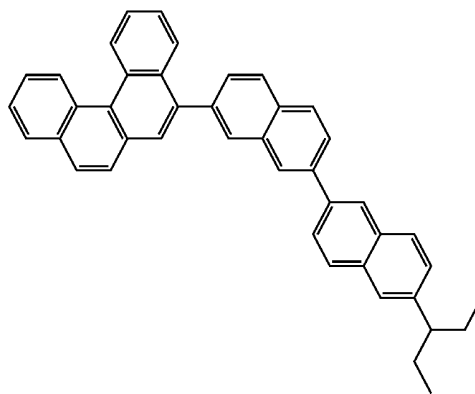


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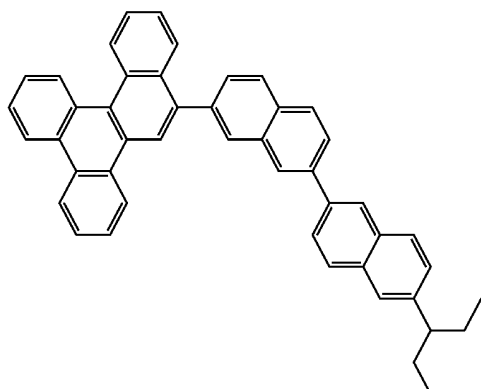
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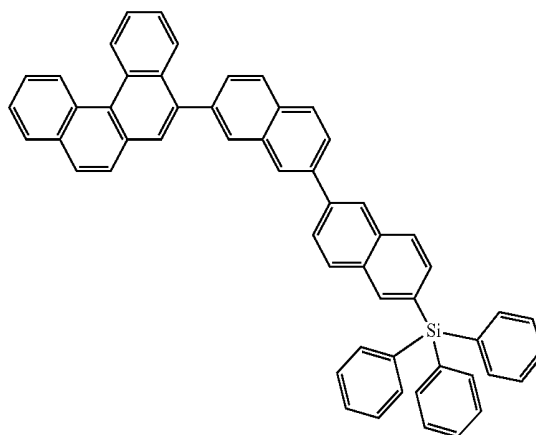
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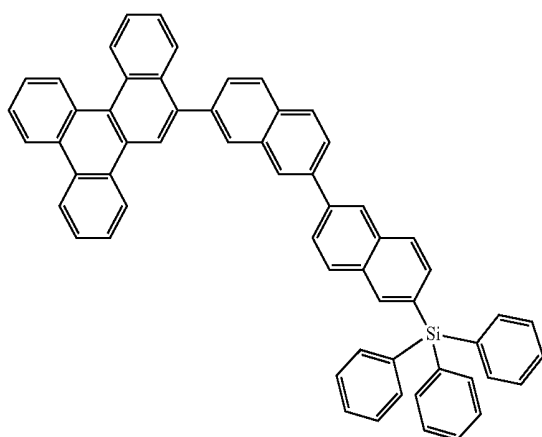
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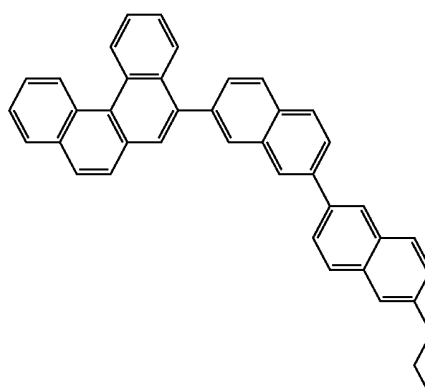
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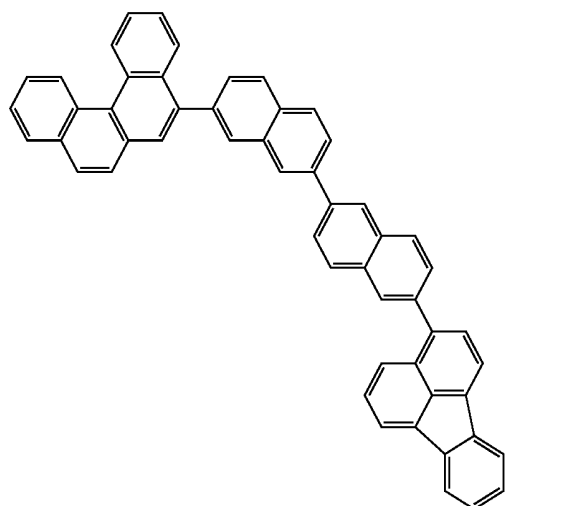
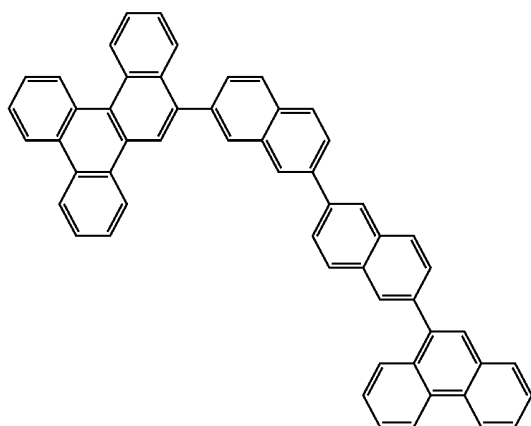
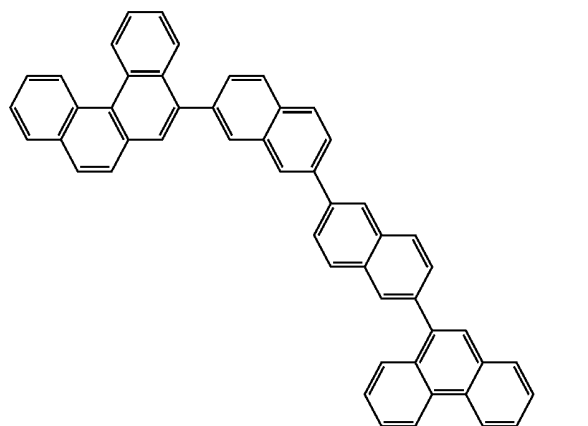
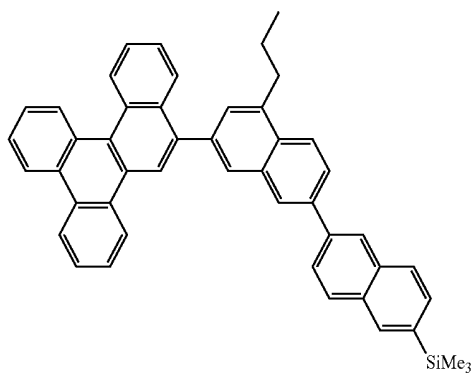
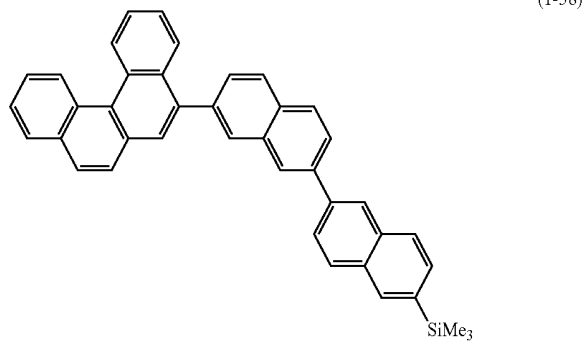
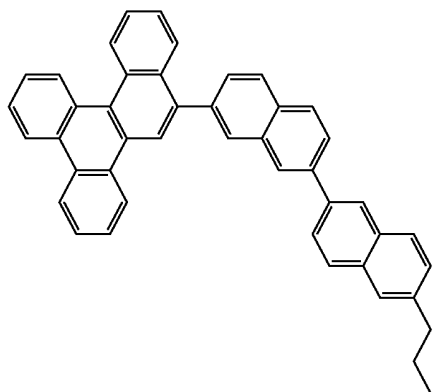
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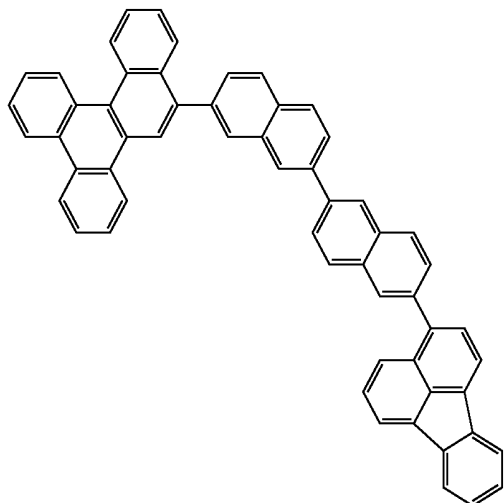


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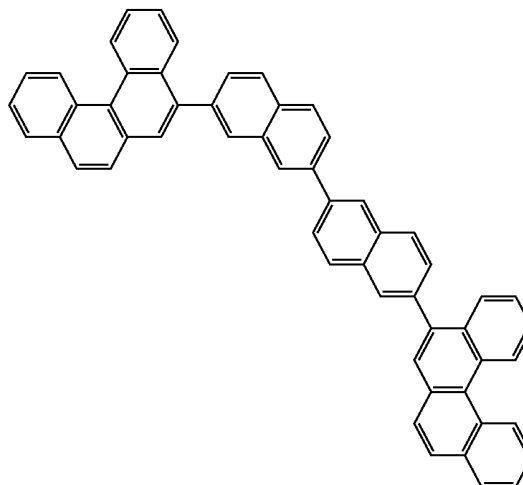


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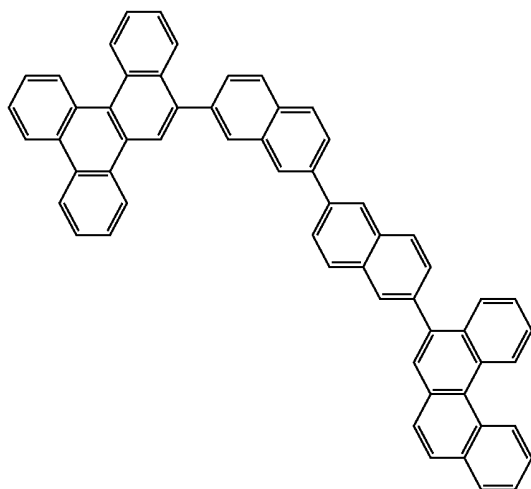
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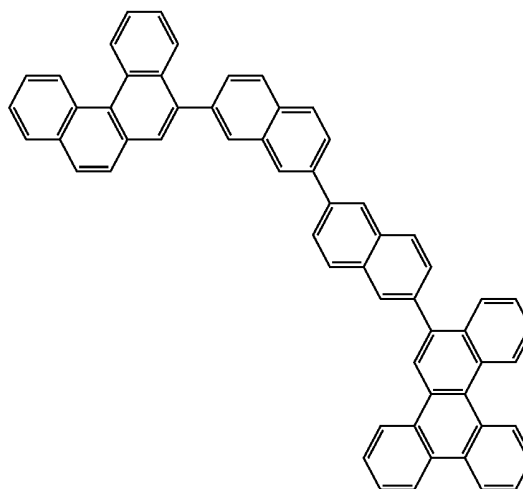
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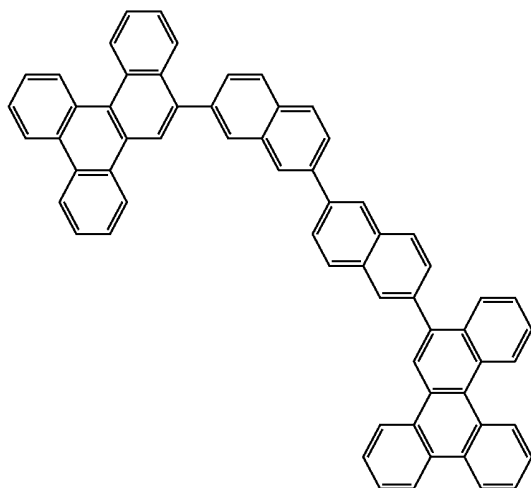
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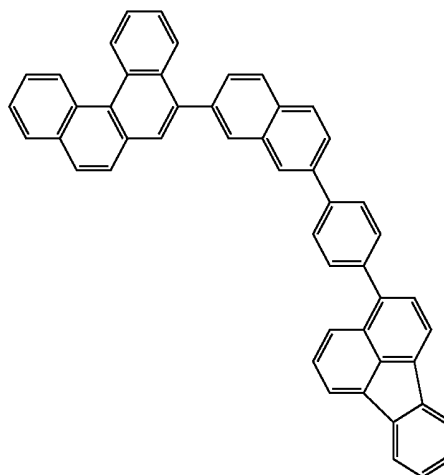
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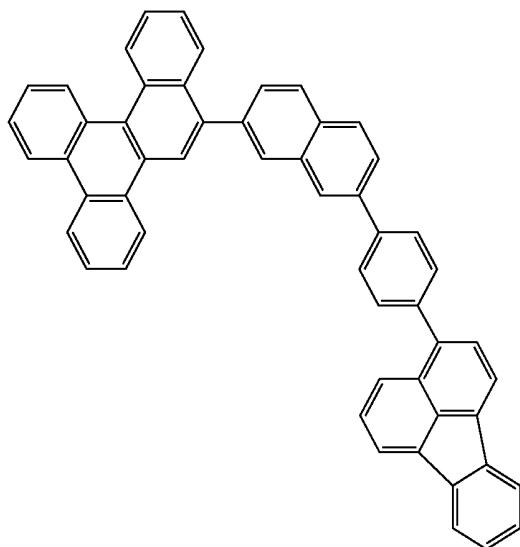


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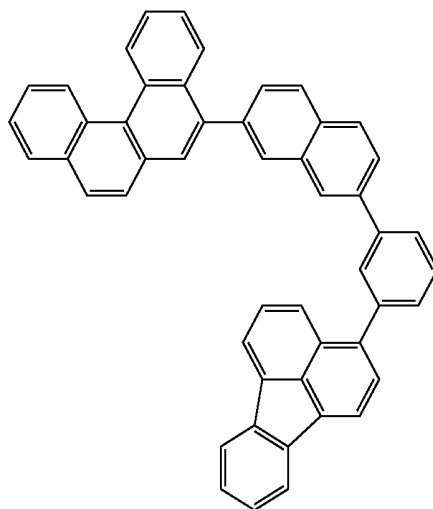


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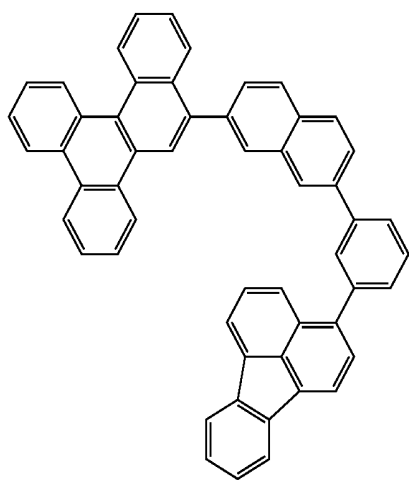
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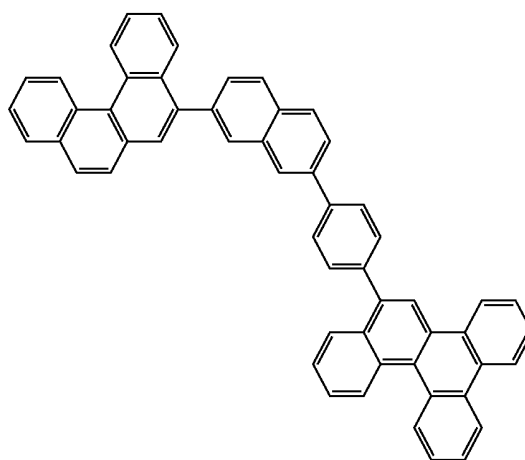
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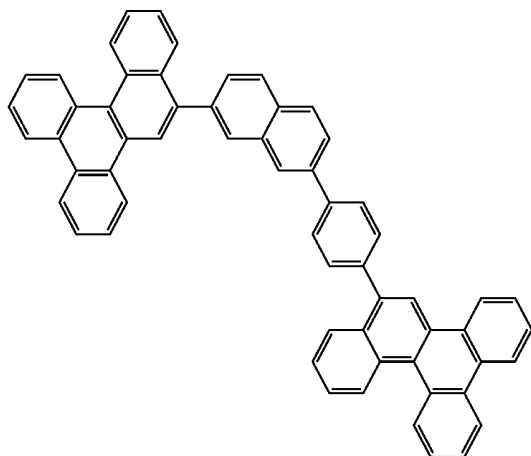
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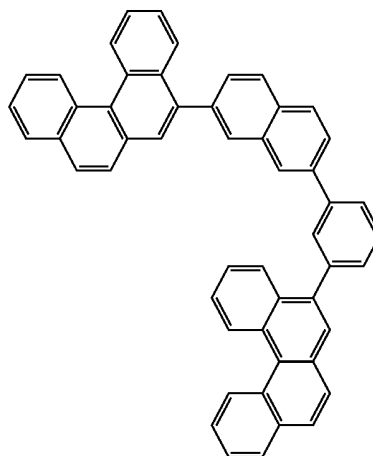
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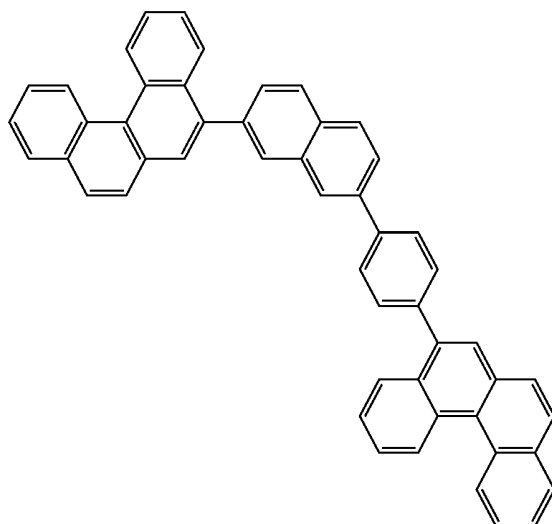
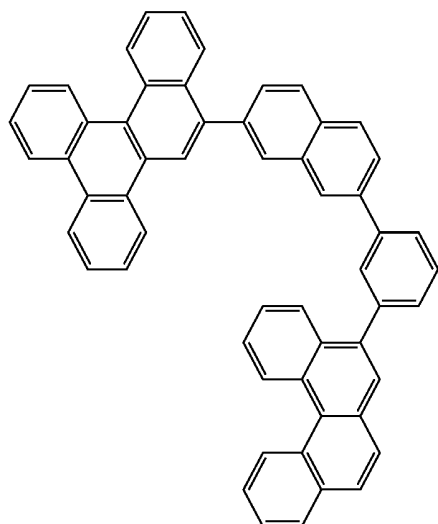


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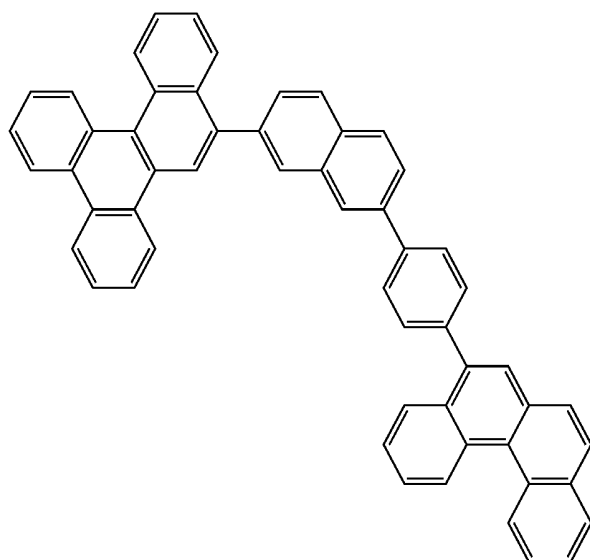


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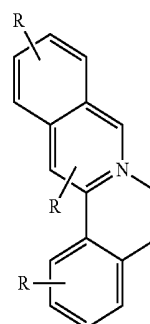


[0104] With regard to phosphorescent emitter materials capable of use in the OLEDs of the present invention, Ir(2-phenylquinoline) and Ir(1-phenylisoquinoline) type phosphorescent materials have been synthesized, and OLEDs incorporating them as the dopant emitters have been fabricated. Such devices may advantageously exhibit high current efficiency, high stability, narrow emission, high processability (such as high solubility and low evaporation temperature), high luminous efficiency, and/or high luminous efficiency.

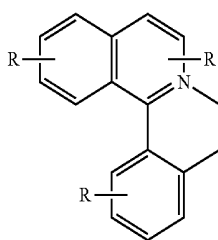
[0105] Using the base structure of Ir(3-Meppy)₃, different alkyl and fluoro substitution patterns have been studied to establish a structure-property relationship with respect to material processability (evaporation temperature, evaporation stability, solubility, etc.) and device characteristics of Ir(2-phenylquinoline) and Ir(1-phenylisoquinoline) type phosphorescent materials. Alkyl and fluoro substitutions are particularly important because they offer a wide range of tenability in terms of evaporation temperature, solubility, energy levels, device efficiency, etc. Moreover, they are stable as functional groups chemically and in device operation when applied appropriately.

[0106] In one embodiment of the present invention, the phosphorescent emitter material comprises a phosphorescent organometallic complex having a substituted chemical structure represented by one of the following partial chemical structures represented by the following formulas (B-1), (B-2) and (B-3):

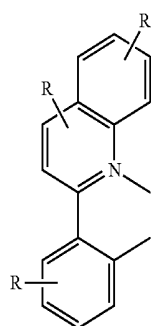
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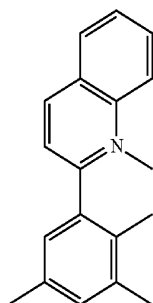
(B-2)



(B-3)

[0107] wherein R is independently hydrogen or an alkyl substituent having 1-3 carbon atoms, and wherein at least one ring of the formula has one or more of said alkyl substituent. In particular, the “substituted” structures include at least one methyl substituent, which may be substituted on any one of the rings. The phosphorescent organometallic complex according to the above structure may be substituted with any suitable number of methyl groups. Preferably the phosphorescent organometallic complex according to the above structure is substituted with at least two methyl groups.

[0108] Preferably the phosphorescent organometallic complex according to the above structure is substituted with at least two methyl groups. In a most preferred embodiment, the phosphorescent emitter material comprises a phosphorescent organometallic complex having a substituted chemical structure represented by the following partial chemical structure (3):

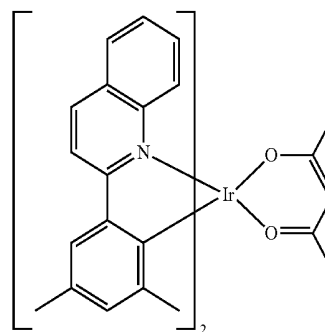


(3)

[0109] In another embodiment, the phosphorescent emitter material comprises a metal complex, and the metal complex comprises a metal atom selected from Ir, Pt, Os, Au, Cu, Re and Ru and a ligand. In yet another embodiment the metal complex has an ortho-metal bond. The metal atom is preferably Ir.

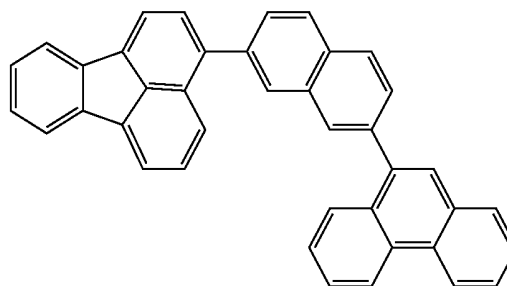
[0110] In another embodiment, the phosphorescent emitter material comprises a phosphorescent organometallic com-

pound having a substituted chemical structure represented by the following chemical structure (4):



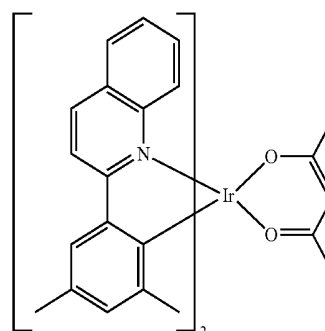
(4)

[0111] In a preferred embodiment, the present invention relates to an OLED wherein the host material comprises an unsubstituted aromatic hydrocarbon compound having the chemical structure represented by the following formula (RH-1):



(RH-1)

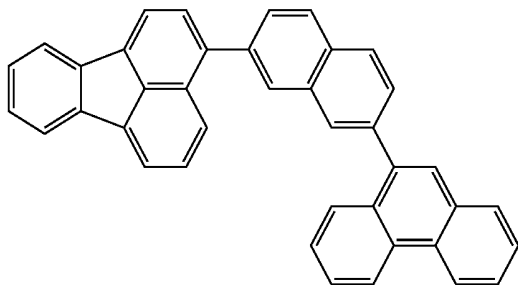
[0112] and wherein the phosphorescent emitter material comprises a phosphorescent organometallic compound having a substituted chemical structure represented by the following chemical structure (4):



(4)

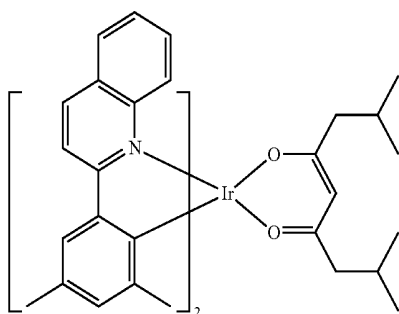
[0113] In another preferred embodiment, the present invention relates to an OLED wherein the host material comprises an unsubstituted aromatic hydrocarbon compound having the chemical structure represented by the following formula (RH-1):

(RH-1)



[0114] and wherein the phosphorescent emitter material comprises a phosphorescent organometallic compound having a substituted chemical structure represented by the following chemical structure (RD-1):

(RD-1)



[0115] The OLEDs of the present invention may comprise a hole transporting layer (hole injecting layer), and the hole transporting layer (hole injecting layer) preferably contains the materials of the present invention. Also, the OLEDs of the present invention may comprise an electron transporting layer and/or a hole blocking layer, and the electron transporting layer and/or hole blocking layer preferably contains the materials of the present invention.

[0116] The OLEDs of the present invention may contain a reductant dopant in an interlayer region between the cathode and the organic thin film layer. Such an OLED having the described structural constitution, may exhibit improved emission luminance and extended lifetime.

[0117] The reductant dopant includes at least one dopant selected from alkali metals, alkali metal complexes, alkali metal compounds, alkali earth metals, alkali earth metal complexes, alkali earth metal compounds, rare earth metals, rare earth metal complexes, rare earth metal compounds and the like.

[0118] Suitable alkali metals include Na (work function: 2.36 eV), K (work function: 2.28 eV), Rb (work function: 2.16 eV), Cs (work function: 1.95 eV) and the like, and the compounds having a work function of 2.9 eV or less are particularly preferred. Among them, K, Rb and Cs are preferred, more preferred are Rb or Cs, and even more preferred is Cs.

[0119] The alkali earth metals include Ca (work function: 2.9 eV), Sr (work function: 2.0 to 2.5 eV), Ba (work function: 2.52 eV) and the like, and the compounds having a work function of 2.9 eV or less are particularly preferred.

[0120] The rare earth metals include Sc, Y, Ce, Tb, Yb and the like, and the compounds having a work function of 2.9 eV or less are particularly preferred.

[0121] Among the metals described above, it is preferred to select metals having a high reducing ability, and addition of a relatively small amount thereof to the electron injecting region may make it possible to enhance the emission luminance and extend the lifetime of the OLED.

[0122] The alkali metal compounds include alkali metal oxides such as Li_2O , Cs_2O , K_2O and the like and alkali metal halides such as LiF , NaF , CsF , KF and the like. Preferred compounds include LiF , Li_2O and NaF .

[0123] The alkali earth metal compounds include BaO , SrO , CaO and $\text{Ba}_x\text{Sr}_{1-x}\text{O}$ ($0 < x < 1$), $\text{Ba}_x\text{Ca}_{1-x}\text{O}$ ($0 < x < 1$) and the like which are obtained by mixing the above compounds, and BaO , SrO and CaO are preferred.

[0124] The rare earth metals compound include YbF_3 , ScF_3 , ScO_3 , Y_2O_3 , Ce_2O_3 , GdF_3 , TbF_3 and the like, and YbF_3 , ScF_3 and TbF_3 are preferred.

[0125] The alkali metal complex, the alkali earth metal complex and the rare earth metal complex shall not specifically be restricted as long as they contain at least one metal ion of alkali metal ions, alkali earth metal ions and rare earth metal ions. The ligand is preferably quinolinol, benzoquinolinol, acridinol, phenanthridinol, hydroxyphenyloxazole, hydroxyphenylthiazole, hydroxydiaryloxadiazole, hydroxydiarylthiadiazole, hydroxyphenylpyridine, hydroxyphenylbenzimidazole, hydroxybenzotriazole, hydroxyfulvorane, bipyrindyl, phenanthroline, phthalocyanine, porphyrin, cyclopentadiene, β -diketones, azomethines and derivatives thereof. However, suitable materials are not restricted to the above-mentioned compounds.

[0126] The reductant dopant may be formed in an interfacial region, and is preferably in a layer form or an island form. The forming method may be a method in which a light emitting material forming an interfacial region and an organic substance corresponding to an electron injecting material are deposited at the same time while depositing the reductant dopant by a resistance heating vapor deposition method to thereby disperse the reductant dopant in the organic substance. The dispersion concentration has a ratio of organic substance to reductant dopant of from about 100:1 to 1:100, and preferably from about 5:1 to 1:5 in terms of the mole ratio.

[0127] When the reductant dopant is formed in a layer form, the light emitting material which is an organic layer in an interfacial region and the electron injecting material are formed in a layer form, and then the reductant dopant may be deposited alone by the resistance heating vapor deposition method to form the layer preferably in a thickness of 0.1 to 15 nm.

[0128] When the reductant dopant is formed in an island form, the light emitting material which is an organic layer in an interfacial region and the electron injecting material are formed in an island form, and then the reductant dopant may be deposited alone by the resistance heating vapor deposition method to form the island preferably in a thickness of 0.05 to 1 nm.

[0129] A mole ratio of the main component to the reductant dopant in the OLEDs of the present invention is preferably main component:reductant dopant=5:1 to 1:5, more preferably 2:1 to 1:2 in terms of a mole ratio.

[0130] The OLEDs of the present invention preferably have an electron injecting layer between the light emitting layer and the cathode. In this regard, the electron injecting layer

may be a layer which functions as an electron transporting layer. The electron injecting layer or the electron transporting layer is a layer for assisting injection of an electron into the light emitting layer, and it has a large electron mobility. The electron injecting layer is provided to control an energy level including relaxation of a sudden change in the energy level.

[0131] The forming methods of the respective layers in the OLEDs of the present invention shall not specifically be restricted, and forming methods carried out by a vacuum vapor deposition method, a spin coating method and the like which have so far publicly been known can be used. The organic thin film layer containing the host material compounds represented by the formula (1) described above which is used for the OLEDs of the present invention can be formed by known methods such as by vacuum vapor deposition, molecular beam evaporation (MBE method), and coating methods such as dipping, spin coating, casting, bar coating and roll coating, each using a solution prepared by dissolving the compound in a solvent.

[0132] The film thicknesses of the respective organic layers in the OLEDs of the present invention shall not specifically be restricted. In general, too small film thicknesses may be associated with defects such as pinholes and the like, while too large film thicknesses require application of high voltage, and may lower the OLED's efficiency. Accordingly, film thicknesses are typically in the range of one to several nm to 1 μ m.

[0133] By the combination of the present invention, the triplet energy level of the phosphorescent dopant and the triplet energy level of the host are properly regulated. As a result thereof, an organic EL device with a high efficiency and an extended lifetime is obtained.

[0134] Of the host materials of the present invention, the fluoranthene derivative is particularly effective for an extended lifetime. As compared with fluoranthene, the fluoranthene derivative has a small triplet energy level. It has been found, therefore, that the fluoranthene derivative exhibits the effect of the present invention when combined with the phosphorescent dopant of the present invention.

[0135] The host material (1) for organic EL devices represented by the chemical formula (1) is asymmetric with respect to the 2,7-disubstituted naphthalene ring and the host material (2) for organic EL devices represented by the chemical formula (2) is asymmetric with respect to the 2,7-disubstituted naphthalene ring —Ar⁵-2,7-disubstituted naphthalene ring structure. With such asymmetric structures, the lifetimes and other performance of organic EL devices having those host materials in their light emitting layers are dramatically improved.

[0136] As the host materials (1) and (2) for organic EL devices of the present invention each have a large triplet energy gap (excited triplet energy), each of the materials can transfer energy to a phosphorescent dopant to cause the dopant to emit phosphorescent light.

[0137] In addition, an anthracene derivative well known as a fluorescent host is unsuitable as a host for the red light emitting phosphorescent dopant of the present invention. However, the triplet energy gap of each host materials (1) and (2) of the present invention is large, and hence the phosphorescent dopant that emits red light can be effectively caused to emit light.

[0138] In addition, in the present invention, the skeleton of each material for organic EL devices is formed of a polycyclic condensed ring free of nitrogen atom, and hence the molecular stability can be improved and the lifetime of the organic

EL device can be lengthened. The molecular stability is not sufficiently high when the number of ring atoms of the skeleton portion is excessively small. On the other hand, when the number of rings in the polycyclic condensed ring of each compound of the present invention is excessively large, the conjugation system excessively extends to narrow the HOMO-LUMO gap, thereby making the triplet energy gap too small for emitting light with intended wavelength, in the red region. Each of the disclosed materials (1) and (2) for organic EL devices is suitable as a phosphorescent host for a phosphorescent light emitting layer emitting light with intended wavelength (red) and having high stability because each of the materials has a moderate number of ring atoms.

[0139] Ar¹ and Ar² in the host material compound formula (1) each independently represent preferably a benzene ring or the condensed aromatic hydrocarbon ring. More preferably, Ar¹ and Ar² represent different condensed aromatic hydrocarbon rings. In addition, Ar¹ preferably represents a ring selected from a phenanthrene ring, a fluoranthene ring, a benzophenanthrene ring, and a benzochrysene ring. More preferably, Ar¹ is a ring selected from a phenanthrene ring, a fluoranthene ring, a benzophenanthrene ring, and a benzochrysene ring, and Ar² is a benzene ring or a naphthalene ring.

[0140] When Ar⁵ in the host material formula (2) is a benzene ring, Ar⁴ and Ar⁶ preferably each independently represent a condensed aromatic hydrocarbon ring selected from a chrysene ring, a fluoranthene ring, a benzophenanthrene ring, a dibenzophenanthrene ring, a benzotriphenylene ring, a benzochrysene ring, a benzo[b]fluoranthene ring, and a picene ring. More preferably, Ar⁴ and Ar⁶ are different condensed aromatic hydrocarbon rings. In the host material formula (2), it is preferred that R⁴ and R⁵ each represent a hydrogen atom, and Ar⁴ or Ar⁶ represent a group selected from a phenanthrene ring, a fluoranthene ring, a benzophenanthrene ring, and a benzochrysene ring. More preferably, Ar⁵ has 10 or more ring forming carbon atoms, and Ar⁴ or Ar⁶ represents a ring selected from a phenanthrene ring, a fluoranthene ring, a benzophenanthrene ring, and a benzochrysene ring.

[0141] Ar⁵ preferably represents a dibenzofuran ring. In a particularly preferred material having the asymmetric structure of the present invention, Ar¹ to Ar³, Ar⁴ to Ar⁶ each independently represent a group excellent in heat resistance, such as a substituted or unsubstituted phenanthrene ring, a substituted or unsubstituted fluoranthene ring, a substituted or unsubstituted benzophenanthrene ring, or a substituted or unsubstituted benzochrysene ring.

[0142] Preferred examples of the one or more optional substituents for R¹ to R³, Ar¹ to Ar³, and the 2,7-disubstituted naphthalene ring in the host material formula (1), and R⁴ and R⁵, Ar⁴ to Ar⁶, and two 2,7-disubstituted naphthalene rings in the host material formula (2) include an aryl group having 6 to 22 carbon atoms, an alkyl group having 1 to 20 carbon atoms, a haloalkyl group having 1 to 20 carbon atoms, a cycloalkyl group having 5 to 18 carbon atoms, an unsubstituted or a substituted silyl group having 3 to 20 carbon atoms, a cyano group, and a halogen atom, with an aryl group having 6 to 14 carbon atoms exclusive of an anthracene ring, an alkyl group having 1 to 20 carbon atoms, a haloalkyl group having 1 to 20 carbon atoms, a cycloalkyl group having 5 to 18 carbon atoms, and an unsubstituted or a substituted silyl group having 3 to 20 carbon atoms being more preferred.

[0143] As those substituents are free of nitrogen atoms, the stability of each material for organic EL device can be additionally improved and the lifetime of device can be addition-

ally lengthened. The number of substituents of R^1 to R^3 , Ar^1 to Ar^3 , and the 2,7-disubstituted naphthalene ring in the host formula (1), and R^4 , R^5 , Ar^4 to Ar^6 , and two 2,7-disubstituted naphthalene rings in the host formula (2) is preferably 2 or less, and more preferably 1 or less.

[0144] Preferred examples of the aryl substituent having 6 to 22 carbon atoms include phenyl group, biphenyl group, terphenyl group, naphthyl group, phenylnaphthyl group, naphthylphenyl group, naphthylphenyl group, phenylphenanthrenyl group, chrysenyl group, fluoranthenyl group, 9,10-dialkylfluorenyl group, 9,10-diarylfluorenyl group, triphenylenyl group, phenanthrenyl group, benzophenanthrenyl group, dibenzophenanthrenyl group, benzotriphenylenyl group, benzochrysenyl group, and dibenzofuranyl group, with an aryl group having 6 to 18 carbon atoms, such as phenyl group, biphenyl group, terphenyl group, naphthyl group, chrysenyl group, phenylnaphthyl group, naphthylphenyl group, fluoranthenyl group, 9,10-dimethylfluorenyl group, triphenylenyl group, phenanthrenyl group, benzophenanthrenyl group, and dibenzofuranyl group, being more preferred, and an aryl group having 6 to 14 carbon atoms, such as phenyl group, biphenyl group, naphthyl group, phenanthrenyl group, and dibenzofuranyl group, being still more preferred.

[0145] Examples of the alkyl group having 1 to 20 carbon atoms include a methyl group, ethyl group, propyl group, isopropyl group, n-butyl group, s-butyl group, isobutyl group, t-butyl group, n-pentyl group, n-hexyl group, n-heptyl group, n-octyl group, n-nonyl group, n-decyl group, n-undecyl group, n-dodecyl group, n-tridecyl group, n-tetradecyl group, n-pentadecyl group, n-hexadecyl group, n-heptadecyl group, n-octadecyl group, neopentyl group, 1-methylpentyl group, 2-methylpentyl group, 1-pentylhexyl group, 1-butylpentyl group, 1-heptyloctyl group, and 3-methylpentyl group.

[0146] Examples of the haloalkyl group having 1 to 20 carbon atoms include chloromethyl group, 1-chloroethyl group, 2-chloroethyl group, 2-chloroisobutyl group, 1,2-dichloroethyl group, 1,3-dichloroisopropyl group, 2,3-dichloro-t-butyl group, 1,2,3-trichloropropyl group, bromomethyl group, 1-bromoethyl group, 2-bromoethyl group, 2-bromoisobutyl group, 1,2-dibromoethyl group, 1,3-dibromoisopropyl group, 2,3-dibromo-t-butyl group, 1,2,3-tribromopropyl group, iodomethyl group, 1-iodoethyl group, 2-iodoethyl group, 2-iodoisobutyl group, 1,2-diiodoethyl group, 1,3-diiodoisopropyl group, 2,3-diiodo-t-butyl group, and 1,2,3-triiodopropyl group.

[0147] Examples of the cycloalkyl group having 5 to 18 carbon atoms include cyclopentyl group, cyclohexyl group, cyclooctyl group, and 3,5-tetramethylcyclohexyl group, with cyclohexyl group, cyclooctyl group, and 3,5-tetramethylcyclohexyl group being preferred.

[0148] The silyl group having 3 to 20 carbon atoms may preferably include an alkylsilyl group, an arylsilyl group, and an aralkylsilyl group. Examples thereof include trimethylsilyl group, triethylsilyl group, tributylsilyl group, trioctylsilyl group, triisobutylsilyl group, dimethylethylsilyl group, an unsubstituted or a dimethylisopropylsilyl group, dimethylpropylsilyl group, dimethylbutylsilyl group, dimethyl-t-butylsilyl group, diethylisopropylsilyl group, phenyldimethylsilyl group, diphenylmethylsilyl group, diphenyl-t-butylsilyl group, and triphenylsilyl group. Examples of the halogen atom include fluorine atom, chlorine atom, bromine atom, and iodine atom.

[0149] Ar^3 in the host formula (1) is preferably a ring selected from a substituted or unsubstituted phenanthrene ring, a substituted or unsubstituted fluoranthene ring, and a substituted or unsubstituted benzophenanthrene ring.

[0150] By selecting the above ring structure, a thin film for organic electroluminescence devices excellent in stability can be formed, and particularly, a high-efficiency, long-lifetime device is obtained when combinedly used with a red phosphorescent material.

[0151] The host materials (1) and (2) for organic EL devices of the present invention preferably have excited triplet energy of 2.0 eV or more and 2.8 eV or less. If being 2.0 eV or more, the energy can be transferred to a phosphorescent light emitting material that emits light having a wavelength of 520 nm or more and 720 nm or less. If being 2.8 eV or less, the problem of inefficient light emission due to an excessively large difference in energy gap with respect to a red phosphorescent dopant can be avoided.

[0152] The excited triplet energy of the host materials (1) and (2) is more preferably 2.0 eV or more and 2.7 eV or less, and still more preferably 2.1 eV or more and 2.7 eV or less.

[0153] The present invention further provides an organic electroluminescence device which has an organic thin film layer with one or more layers between a cathode and an anode, in which the organic thin film layer contains the disclosed host material (1) or material (2) and at least one kind of a phosphorescent light emitting material.

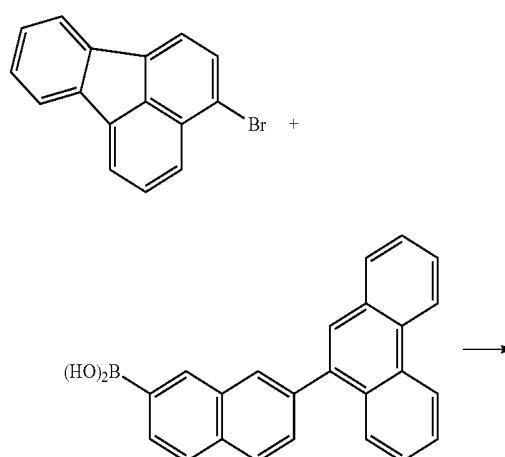
[0154] Next, the invention will be described in further detail with reference to the examples and comparative examples. However, the invention is not limited by the following examples.

EXAMPLES

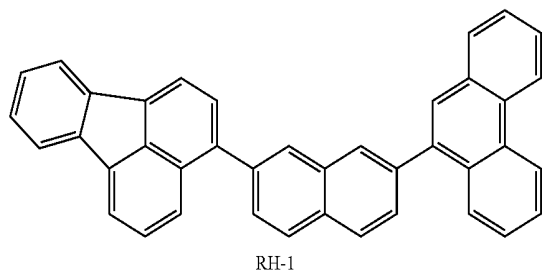
Synthesis Example

Synthesis of Compound (RH-1)

[0155]



-continued



[0156] Under argon atmosphere, a mixture of 5.0 g (18 mmol) of bromide 1-5, 6.2 g (18 mmol) of boronic acid 1-4, 420 mg (0.36 mmol) of tetrakis(triphenylphosphine)palladium(0), 120 ml of toluene, 40 ml of dimethoxyethane, and 26 ml of a 2 M aqueous solution of sodium carbonate was stirred at 90° C. for 15 hours. The reaction mixture was left stand to cool to room temperature, added with water, stirred at room temperature for one hour, and then extracted with toluene. After liquid separation, the organic phase was washed with a saturated saline solution and dried over anhydrous sodium sulfate. The solvent was removed by distillation under reduced pressure. The residue was purified by silica gel column chromatography and recrystallized from toluene, to obtain 6.2 g of compound (1-6) in 68% yield. FD mass spectrometry showed a peak m/e at 504, corresponding to its molecular weight of 504.

Manufacturing of Organic EL Device

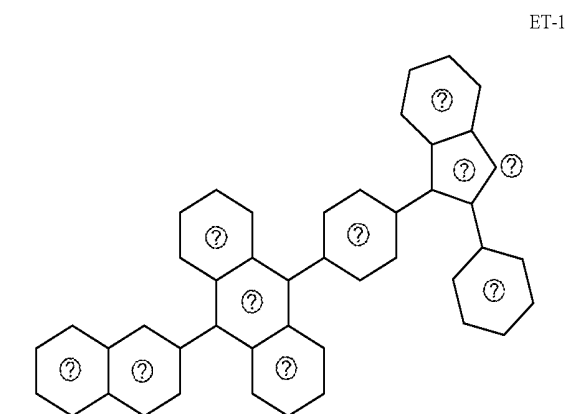
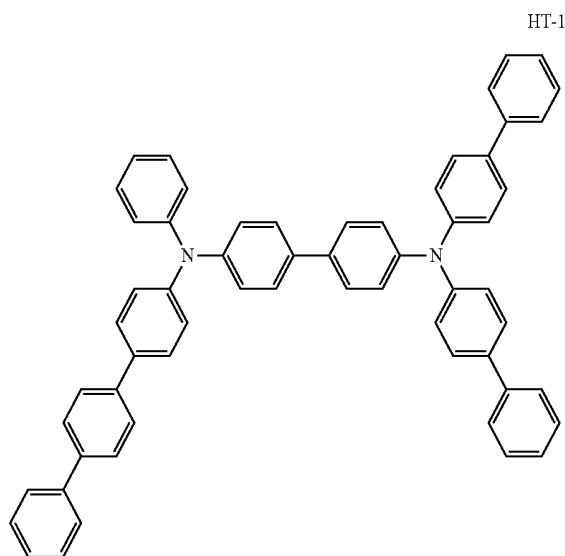
Example 1

[0157] A glass substrate (size: 25 mm×75 mm×1.1 mm) having an ITO transparent electrode (manufactured by Geomatec Co., Ltd.) was ultrasonic-cleaned in isopropyl alcohol for five minutes, and then UV (Ultraviolet)/ozone-cleaned for 30 minutes.

[0158] After the glass substrate having the transparent electrode was cleaned, the glass substrate was mounted on a substrate holder of a vacuum deposition apparatus. A hole transporting layer was initially formed by vapor-depositing HT-1 in a thickness of 50 nm to cover a surface of the glass substrate where the transparent electrode lines were provided.

[0159] A red phosphorescent-emitting layer was obtained by co-depositing RH-1 as a red phosphorescent host and RD-1 as a red phosphorescent dopant onto the hole transporting layer in a thickness of 40 nm. The concentration of RD-1 was 8 wt %.

[0160] Then, a 40-nm-thick ET-1 layer, a 1-nm-thick LiF layer and a 80-nm-thick metal Al layer were sequentially formed to obtain a cathode. A LiF layer, which was an electron injectable electrode, was formed at a speed of 1 Å/sec. Structures of HT-1 and ET-1 are as follows:



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Comparative Example 1

[0161] An organic EL device was prepared in the same manner as Example 1 except that CBP (4,4'-bis(N-carbazolyl)biphenyl) was used instead of RH-1 as the red phosphorescent host and Ir(piq)₃ was used instead of RD-1 as the red phosphorescent dopant.

Comparative Example 2

[0162] An organic EL device was prepared in the same manner as Example 1 except that Ir(piq)₃ was used instead of RD-1 as the red phosphorescent dopant.

Comparative Example 3

[0163] An organic EL device was prepared in the same manner as Example 1 except that CBP was used instead of RH-1 as the red phosphorescent host.

[0164] The structures of the devices according to the Example 1 and Comparative Examples 1 to 3 are shown in Table 1.

TABLE 1

	Hole Transporting Layer	Red Phosphorescent Emitting Layer	Electron Transporting Layer
Example 1	HT-1	8% RD-1 RH-1	ET-1
Comparative Example 1	HT-1	8% Ir(piq)3 CBP	ET-1
Comparative Example 2	HT-1	8% Ir(piq)3 RH-1	ET-1
Comparative Example 3	HT-1	8% RD-1 CBP	ET-1

[0165] Evaluation of Organic EL Device

[0166] The organic EL devices each manufactured in Example 1 and Comparative Examples 1 to 3 were driven by direct-current electricity of 1 mA/cm² to emit light, to measure the emission chromaticity, the luminescence (L) and the voltage. Using the measured values, the current efficiency (L/J) and the luminance efficiency η (lm/W) were obtained. The results are shown in Table 2.

TABLE 2

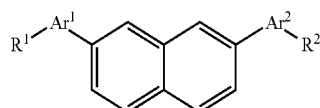
			Voltage	Current Efficiency	Luminous Efficiency	Chromaticity (CIE Color system)		LT80 @20,000 cd/m ²	LT50 @20,000 cd/m ²
	Emitter	Host	(V)	(cd/A)	(lm/W)	x	y	(hrs)	(hrs)
Example									
1	RD-1	RH-1	2.99	17.1	17.9	0.672	0.328	70	650
Comparative Examples									
1	Ir(piq)3	CBP	4.38	7.6	5.4	0.678	0.321	3	5
2	Ir(piq)3	RH-1	3.74	8.2	6.9	0.681	0.319	4	20
3	RD-1	CBP	3.19	10.7	10.5	0.672	0.328	5	25

[0167] As is clear from Table 2, the organic EL device according to Example 1 exhibited excellent power efficiency and lifetime as compared with the organic EL devices according to Comparative Examples 1 to 3.

What is claimed is:

1. An organic light emitting device comprising an anode, a cathode and an emissive layer, wherein the emissive layer is located between the anode and the cathode, and the emissive layer comprises a host material and a phosphorescent emitter material, wherein:

(a) the host material comprises a substituted or unsubstituted hydrocarbon compound having the chemical structure represented by the following formula (1):



(1)

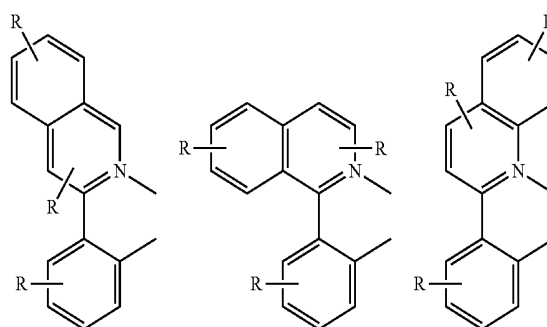
wherein R² represents a hydrogen atom, a benzene ring, a condensed aromatic hydrocarbon ring, a dibenzofuran ring or a group represented by Ar³—R³;

Ar¹ to Ar³ each independently represent a benzene ring, a condensed aromatic hydrocarbon ring or a dibenzofuran ring;

R¹ and R³ each independently represent a hydrogen atom, a benzene ring, a condensed aromatic hydrocarbon ring, or a dibenzofuran ring; the condensed aromatic hydrocarbon ring represented by R¹ to R³ and Ar¹ to Ar³ is selected from the group consisting of a naphthalene ring, a chrysene ring, a fluoranthene ring, a triphenylene ring, a phenanthrene ring, a benzophenanthrene ring, a dibenzophenanthrene ring, a benzotriphenylene ring, a benzochrysene ring, and a benzo[b]fluoranthene ring; and R¹ to R³, Ar¹ to Ar³ and 2,7-disubstituted naphthalene ring each independently may have one or more substituents; with the proviso that when Ar¹ and Ar² each represents a condensed aromatic hydrocarbon constituted by four or more-membered ring, Ar¹ and Ar² are different from each other;

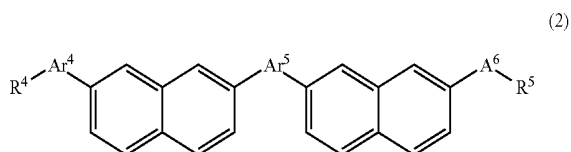
wherein when Ar¹ and Ar² each represents a benzene ring, R¹ and R² cannot both be a hydrogen atom or a naphthalene ring at the same time; and when R¹ and R² each represents a hydrogen atom, Ar¹ and Ar² cannot both be a naphthalene ring at the same time or a combination of a naphthalene ring and a benzene ring; and

(b) the phosphorescent emitter material comprises a phosphorescent organometallic complex having a substituted chemical structure represented by one of the following partial chemical structures represented by the following formulas:



wherein R is independently hydrogen or an alkyl substituent having 1-3 carbon atoms, and wherein at least one ring of the formula has one or more of said alkyl substituent.

2. The organic light emitting device of claim 1, wherein the host material has the chemical structure represented by the following formula:

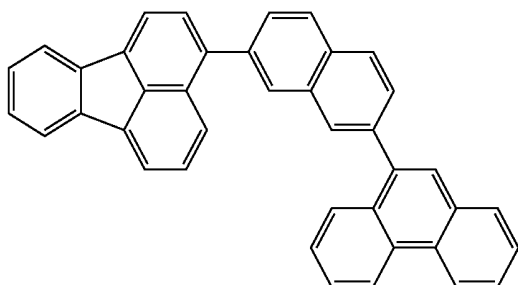


wherein Ar⁴-Ar⁶ are each independently a benzene ring, fused aromatic hydrocarbon ring, or a dibenzofuran ring;

R⁴, R⁵ are each independently a hydrogen atom, benzene ring, fused aromatic hydrocarbon ring, or a dibenzofuran ring; and

R⁴, R⁵, Ar⁴-Ar⁶ and fused aromatic hydrocarbon ring are each independently a naphthalene ring, chrysene ring, fluoranthene ring, triphenylene ring, phenanthrene ring, ring benzophenanthrene, or a benzophenanthrene ring.

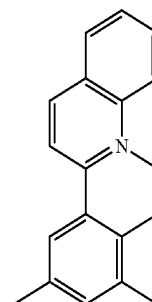
3. The organic light emitting device of claim 1, wherein the host material has the chemical structure represented by the following formula:



4. The organic light emitting device of claim 1, wherein the triplet energy of the host material is from about 2.0 eV to about 2.8 eV.

5. The organic light emitting device of claim 1, wherein the phosphorescent emitter material comprises a phosphorescent organometallic complex wherein the substituted chemical structure is substituted with at least two methyl groups.

6. The organic light emitting device of claim 1, wherein the phosphorescent emitter material comprises a phosphorescent organometallic complex having a substituted chemical structure represented by the following partial chemical structure:

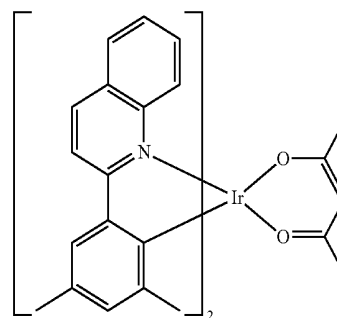


7. The organic light emitting device of claim 1, wherein the phosphorescent emitter material comprises a metal complex, and the metal complex comprises a metal atom selected from Ir, Pt, Os, Au, Cu, Re, Ru and a ligand.

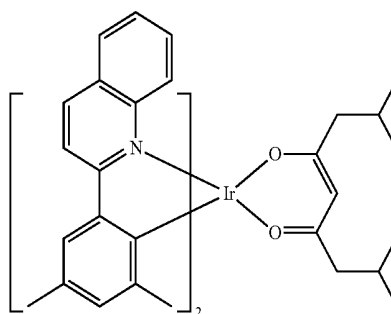
8. The organic light emitting device of claim 6, wherein the metal complex has an ortho-metal bond.

9. The organic light emitting device of claim 7, wherein the metal atom is Ir.

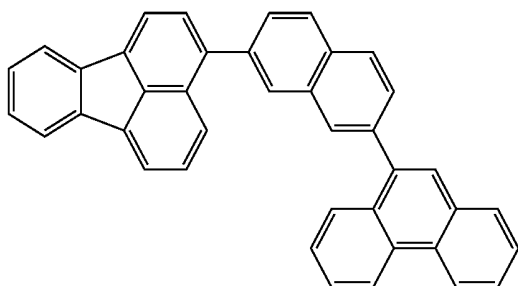
10. The organic light emitting device of claim 1, wherein the phosphorescent emitter material comprises a phosphorescent organometallic compound having a substituted chemical structure represented by the following chemical structure:



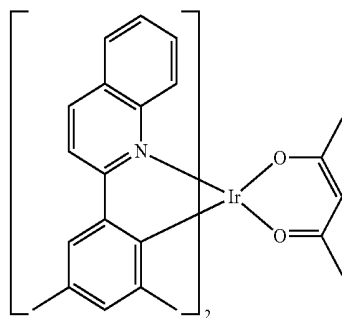
11. The organic light emitting device of claim 1, wherein the phosphorescent emitter material comprises a phosphorescent organometallic compound having a substituted chemical structure represented by the following chemical structure:



12. The organic light emitting device of claim 1, wherein the host material comprises an unsubstituted aromatic hydrocarbon compound having the chemical structure represented by the following formula:

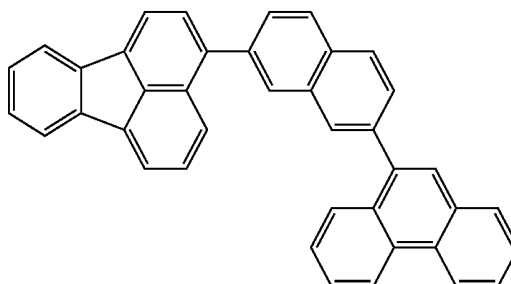


and wherein the phosphorescent emitter material comprises a phosphorescent organometallic compound having a substituted chemical structure represented by the following chemical structure:

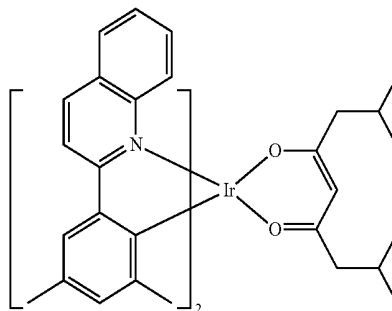


13. The organic light emitting device of claim **12**, wherein at least one of the phosphorescent materials contained in the light emitting layer has a maximum value of 500 nm or more and 720 nm or less in a light emitting wavelength.

14. The organic light emitting device of claim **1**, wherein the host material comprises an unsubstituted aromatic hydrocarbon compound having the chemical structure represented by the following formula:



and wherein the phosphorescent emitter material comprises a phosphorescent organometallic compound having a substituted chemical structure represented by the following chemical structure:



15. The organic light emitting device of claim **14**, wherein at least one of the phosphorescent materials contained in the light emitting layer has a maximum value of 500 nm or more and 720 nm or less in a light emitting wavelength.

* * * * *

专利名称(译)	有机发光器件及其使用的材料		
公开(公告)号	US20130306960A1	公开(公告)日	2013-11-21
申请号	US13/995193	申请日	2011-02-11
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IPC分类号	H01L51/50		
CPC分类号	H01L51/5028 H01L51/0054 H01L51/0058 H01L51/0059 H01L51/0072 H01L51/0085 H01L51/5012		
外部链接	Espacenet USPTO		

摘要(译)

本发明提供一种OLED，其中有有机薄膜发光层包括在阴极和阳极之间的单层或多层，其中有有机薄膜层包括至少一个有机发光层，其中至少一个发光层包含至少一种主体材料和至少一种磷光发光体材料，其中所述主体材料包含具有由下式(1)表示的化学结构的取代或未取代的烃化合物：其中R₂代表氢原子，苯环，稠合芳烃环，二苯并呋喃环或Ar₃-R₃代表的基团；Ar₁-Ar₃各自独立地代表苯环，稠合芳烃环或二苯并呋喃环；R₁ R₃和R₃各自独立地表示氢原子，苯环，稠合芳香烃环或二苯并呋喃环。由R₁至R₃和Ar₁至Ar₃表示的稠合芳烃环选自萘环，环，荧蒹环，三亚苯环，菲环，苯并菲环，二苯并菲环，a苯并三亚苯基环，苯并噻吩环和苯并[b]荧蒹环；R₁至R₃，Ar₁至Ar₃和2,7-二取代萘环各自独立地可具有一个或多个取代基；条件是当Ar₁和Ar₂各自代表由四元或更多元环构成的稠合芳烃时，Ar₁和Ar₂彼此不同；其中当Ar₁和Ar₂各自代表苯环时，R₁和R₂不能同时为氢原子或萘环同时；当R₁和R₂各自代表氢原子时，Ar₁和Ar₂不能同时是萘环或萘环和苯环的组合；磷光发光体材料包括具有取代化学结构的磷光有机金属配合物，所述化学结构由下式表示的下列部分化学结构之一表示：其中每个R独立地选自H，烷基，链烯基，炔基，CN，CF₃，CnF_{2n+1}，三氟乙烯基，CO₂R，C(O)R，NR₂，NO₂，OR，卤素，芳基，杂芳基，取代的杂芳基或杂环基。

